

Revision History**1.8V 128Mbit Serial NOR Flash Memory with 4KB Sectors, Dual and Quad I/O SPI & QPI****AS25F1128MQ-70SIN 8pin SOP Package****AS25F1128MQ-70WIN 8pad WSON Package**

Revision	Details	Date
Rev 1.0	Initial Release	June.2022

1. FEATURES

■ SPI Flash Memory

- 128M-bit / 16M-byte Serial Flash
- 256-bytes per programmable page
- 4K-bit secured OTP

■ Standard, Dual or Quad SPI and QPI

- Standard SPI: CLK, /CS, DI, DO, /WP, /Hold
- Dual SPI: CLK, /CS, IO₀, IO₁, /WP, /Hold
- Quad SPI: CLK, /CS, IO₀, IO₁, IO₂, IO₃
- QPI: CLK, /CS, IO₀, IO₁, IO₂, IO₃

■ High Performance

- 133MHz clock operation
- 266MHz equivalent Dual SPI
- 532MHz equivalent Quad SPI
- 65MB/S continuous data transfer rate
- 40MB/S random access (32-byte fetch)

■ Flexible Architecture

- Uniform Sector Erase (4K-byte)
- Block Erase (32K and 64K-bytes)
- Erase/Program Suspend & Resume
- Accelerated programming mode via 9V ACC pin

■ Endurance

- 100K program/ erase cycles

■ Low Power Consumption

- Single 1.65 to 1.95V supply
- 5mA active current
- <3μA Deep Power-down (typ.)

■ wide Temperature Range

- -40°C to +85°C operating range

■ Advanced Security Features

- Software and Hardware Write-protect
- Top or Bottom, Sector or Block selection
- Lock-Down and OTP protection
- Discoverable Parameters(SFDP) Register

■ Package Options

- 8-pad WSON 6x5-mm
- 8-pin SOP 208-mil

■ Package Material

- Lead-Free & Halogen-Free, ROHS Compliant

2. GENERAL DESCRIPTION

The AS25F1128MQ supports the standard Serial Peripheral Interface (SPI), and Quad Peripheral Interface (QPI): Serial Clock, Chip Select, Serial Data I/O(DI), I/O(DO), I/O(WP), and I/O(HOLD). SPI clock frequencies of up to 133MHz are supported allowing equivalent clock rates of 266MHz for Dual Output and 532MHz for Quad Output when using the QPI and Fast Read Dual/Quad I/O instructions.

The AS25F1128MQ array is organized into 65,536 programmable pages of 256-bytes each. Up to 256 bytes can be programmed at a time using the Page Program instructions. Pages can be erased Sector, 32KB Block, 64KB Block or the entire chip.

The devices operate on a single 1.65V to 1.95V power supply with current consumption as low as 5mA active and 3μA for Deep Power-down. All devices offered in space-saving packages. The device supports JEDEC standard manufacturer and device identification with a 4K-bit Secured OTP.

Table.1 Ordering Information

Part No.	Speed (MHz)	Active Read Current Max. (mA)	Powerdown Current Max. (μA)	Standby Current Max. (μA)	Package
AS25F1128MQ-70SIN	133	27	20	70	8p SOP Package (208mils)
AS25F1128MQ-70WIN					8L WSON Package (6x5mm)

Operating Temperature range : -40°C ~ +85°C
 Suffix "TR" for Tape & Reel Media

3. PIN / PAD CONFIGURATION

3.1 8-Pin SOP 208-MIL

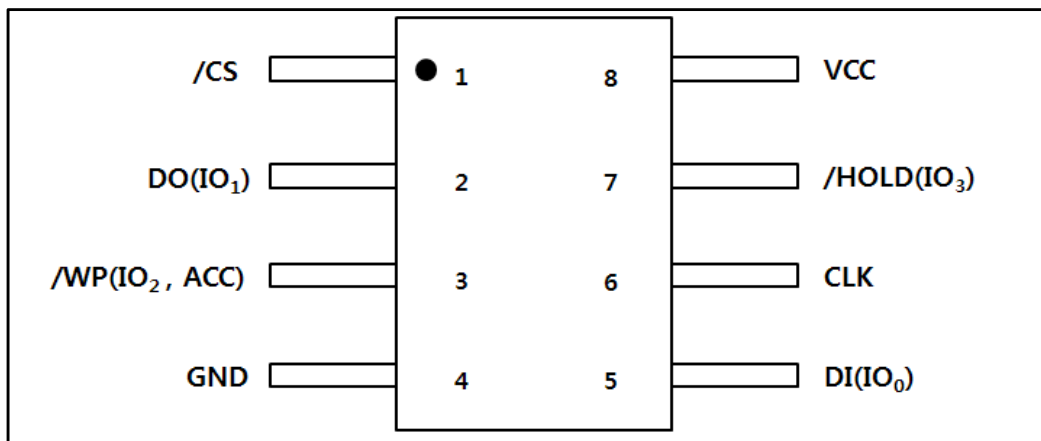


Figure 1a. Pin Assignments, 8-pin SOP 208-mil

3.2 8-Pad WSON 6x5mm

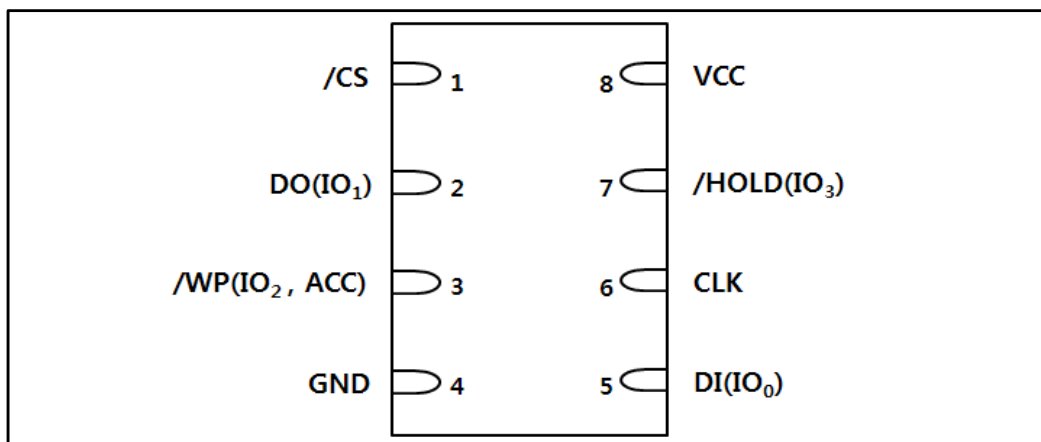


Figure 1b. Pad Assignments, 8-pad WSON

4. PIN / PAD DESCRIPTION

PIN NO.	PIN NAME	I/O	FUNCTION
1	/CS	I	Chip Select Input
2	DO(IO1)	I/O	Data Output (Data Input Output 1)* ¹
3	/WP(IO2, ACC)	I/O	Write Protect Input (Data Input output 2* ² , Acceleration Program)
4	GND		Ground
5	DI(IO0)	I/O	Data Input (Data Input Output 0)* ¹
6	CLK	I	Serial Clock Input
7	/HOLD(IO3)	I/O	Hold Input (Data Input output 3)* ²
8	VCC		Power Supply

*1 IO0 and IO1 are used for Dual and Quad instructions

*2 IO0 – IO3 are used for Quad instructions

4.1 Package Type

AS25F1128MQ is offered in an 8-pin plastic 208-mil width SOP & 6x5-mm WSON as shown in figure 1a and 1b respectively. Package diagrams and dimensions are illustrated at the end of this datasheet.

5. SIGNAL DESCRIPTION

5.1 Chip Select (/CS)

When this input signal is high, the device is deselected and serial data output pins are at high impedance. Unless an internal program, erase or write status register cycle is in progress, the device will be in the standby power mode (this is not the deep power-down mode). Driving Chip Select (/CS) low enables the device, placing it in the active power mode. After power-up, a falling edge on Chip Select (/CS) is required prior to the start of any instruction.

5.2 Serial Data Input, Output and IOs (DI, DO and IO0, IO1, IO2, IO3)

The AS25F1128MQ supports standard SPI, Dual SPI, Quad SPI and QPI operation. Standard SPI instructions use the serial DI (input) pin to write instructions, addresses or data to the device on the rising edge of the Serial Clock (CLK) input pin. Standard SPI also uses the serial DO (output) to read data or status from the device on the falling edge of CLK.

Dual, Quad SPI and QPI instructions use the serial IO pins to write instructions, addresses or data to the device on the rising edge of CLK and read data or status from the device on the falling edge of CLK. Quad SPI instructions require the non-volatile Quad Enable bit (QE) in Status Register-2 to be set. When QE=1 the /WP pin becomes IO2 and /HOLD pin becomes IO3.

5.3 Write Protect (/WP)

The Write Protect (/WP) pin can be used to protect the Status Register against data modification. Used in company with the Status Register's Block Protect (SEC, TB, BP2, BP1 and BP0) bits and Status Register Protect (SRP) bits, a portion or the entire memory array can be hardware protected. The /WP pin is active low. When the QE bit of Status Register-2 is set for Quad I/O, the /WP pin (Hardware Write Protect) function is not available since this pin is used for IO2. See figure 1a, 1b, 1c and 1d for the pin configuration of Quad I/O and QPI operation.

5.4 Accelerated Programming (ACC)

The device offers accelerated program operations through the ACC function. This function is primarily intended to allow faster manufacturing throughput at the factory.

If the system asserts V_{HH} on this pin, the device uses the higher voltage on the pin to reduce the time required for program operations. Removing V_{HH} from the ACC pin returns the device to normal operation.

Note that the ACC pin must not be at V_{HH} for operations other than accelerated programming, or device damage may result. In addition, the ACC pin must not be left floating or unconnected; inconsistent behavior of the device may result.

***Note:** The ACC function is only available during standard SPI Mode.

5.5 HOLD (/HOLD)

The /HOLD pin is used to pause any serial communications with the device without deselecting the device. When /HOLD goes low, while /CS is low, the DO pin will be at high impedance and signals on the DI and CLK pins will be ignored (don't care). When /HOLD goes high, device operation can resume. The /HOLD function can be useful when multiple devices are sharing the same SPI signals. The /HOLD pin is active low. When the QE bit of Status Register-2 is set Quad I/O, the /HOLD pin function is not available since this pin used for IO3. See figure 1a, 1b, 1c and 1d for the pin configuration of Quad I/O and operation.

5.6 Serial Clock (CLK)

This input signal provides the timing for the serial interface. Instructions, addresses, or data present at serial data input are latched on the rising edge of Serial Clock (CLK). Data are shifted out on the falling edge of the Serial Clock (CLK).

6. BLOCK DIAGRAM

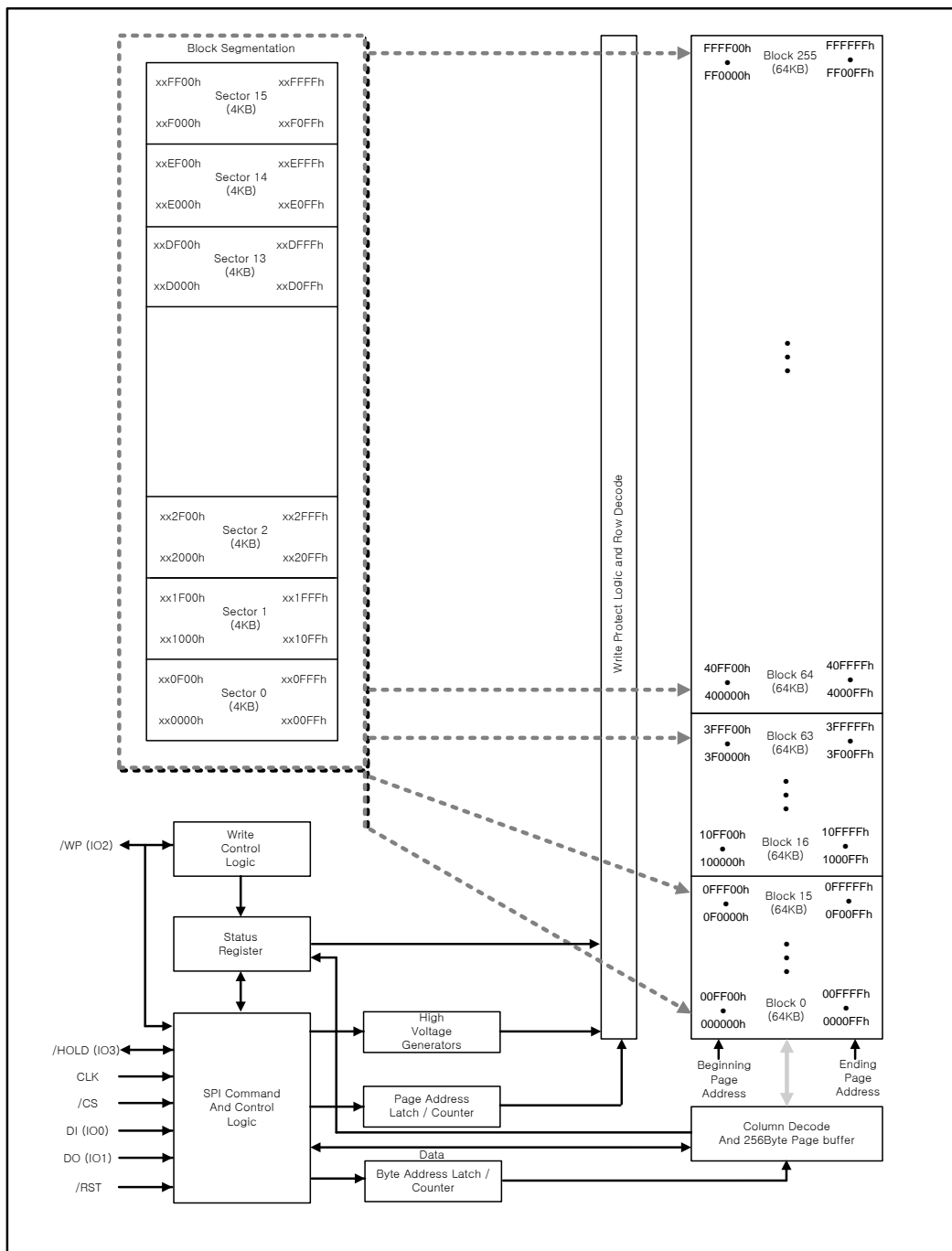


Figure 2. Block Diagram of AS25F1128MQ

7. FUNCTIONAL DESCRIPTION

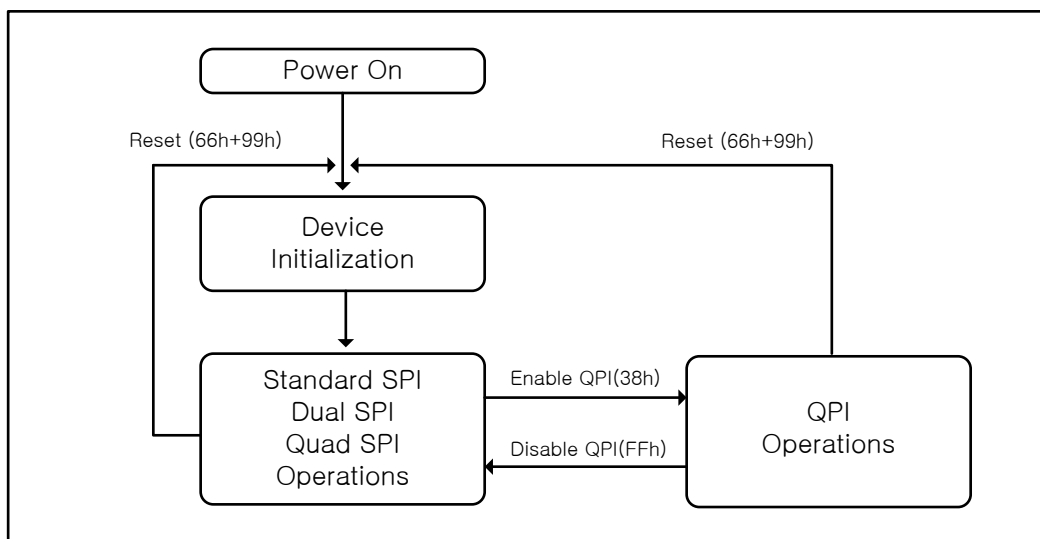


Figure 3. Operation Diagram of AS25F1128MQ

7.1 Standard SPI Instructions

The AS25F1128MQ features a serial peripheral interface on four signals: Serial Clock (CLK), Chip Select (/CS), Serial Data Input (DI) and Serial Data Output (DO). Standard SPI instructions use the DI input pin to serially write instructions, addresses or data to the device on the rising edge of CLK. The DO output pin is used to read data or status from the device on the falling edge of CLK.

SPI bus operation Modes 0 (0, 0) and 3 (1, 1) are supported. The primary difference between Mode 0 and Mode 3 concerns the normal state of the CLK signal when the SPI bus master is in standby and data is not being transferred to the Serial Flash. For Mode 0 the CLK signal is normally low on the falling and rising edges of /CS. For Mode 3 the CLK signal is normally high on the falling and rising edges of /CS.

7.2 Dual SPI Instructions

The AS25F1128MQ supports Dual SPI operation. This instruction allows data to be transferred to or from the device at two times the rate of the standard SPI. The Dual Read instruction is ideal for quickly downloading code to RAM upon power-up (code-shadowing) or for executing non-speed-critical code directly from the SPI bus (XIP). When using Dual SPI instructions the DI and DO pins become bidirectional I/O pins; IO0 and IO1.

7.3 Quad SPI Instructions

The AS25F1128MQ supports Quad SPI operation. This instruction allows data to be transferred to or from the device at four times the rate of the standard SPI. The Quad Read instruction offers a significant improvement in continuous and random access transfer rates allowing fast code-shadowing to RAM or execution directly from the SPI bus (XIP). When using Quad SPI instruction the DI and DO pins become bidirectional IO0 and IO1, and the /WP and /HOLD pins become IO2 and IO3 respectively. Quad SPI instructions require the non-volatile Quad Enable bit (QE) in Status Register-2 to be set.

7.4 QPI Function

The AS25F1128MQ supports Quad Peripheral Interface (QPI) operation when the device is switched from Standard/ Dual/ Quad SPI mode to QPI mode using the “Enable QPI (38h)” instruction. To enable QPI mode, the non-volatile Quad Enable bit (QE) in Status Register-2 is required to be set. When using QPI instructions, the DI and DO pins become bidirectional IO0 and IO1, and the /WP and /HOLD pins become IO2 and IO3 respectively. See Figure 3 for the device operation modes.

The typical SPI protocol requires that the byte-long instruction code being shifted into the device only via DI pin in eight serial clocks. The QPI mode utilizes all four IO pins to input the instruction code, thus only two serial clocks are required. This can significantly reduce the SPI instruction overhead and improve system performance in an XIP environment. Standard/ Dual/ Quad SPI mode and QPI mode are exclusive. Only one mode can be active at any given time, “Enable QPI” and “Disable QPI/ Disable QPI 2” instructions are used to switch between these two modes. Upon power-up or after software reset using “Reset (99h)” instruction, the default state of the device is Standard/ Dual/ Quad SPI mode.

7.5 Hold Function

The /HOLD pin is used to pause a serial sequence of the SPI flash memory without resetting the clocking sequence. To enable the /HOLD mode, the /CS must be in low state. The /HOLD mode effects on with the falling edge of the /HOLD signal with CLK being low. The HOLD mode ends on the rising edge of /HOLD signal with CLK being low.

In other words, /HOLD mode can't be entered unless CLK is low at the falling edge of the /HOLD signal. And /HOLD mode can't be exited unless CLK is low at the rising edge of the /HOLD signal. See Figure.4 for HOLD condition waveform.

If /CS is driven high during a HOLD condition, it resets the internal logic of the device. As long as /HOLD signal is low, the memory remains in the HOLD condition. To re-work communication with the device, /HOLD must go high, and /CS must go low. See 12.12 for HOLD timing.

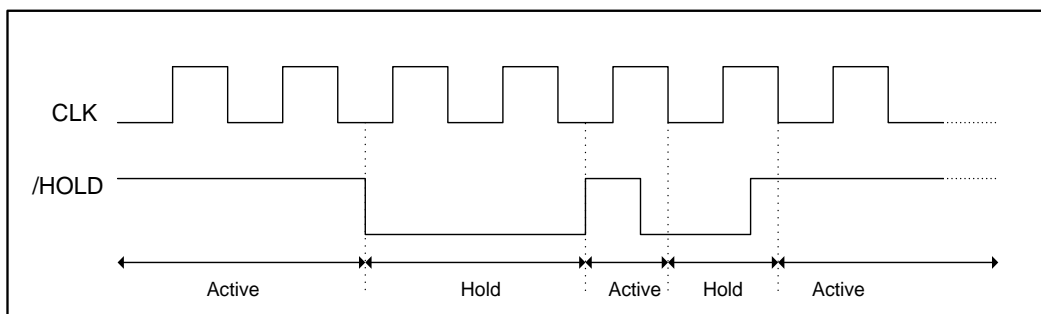


Figure 4. Hold condition waveform (only available Standard/ Dual SPI mode)

8. WRITE PROTECTION

To protect inadvertent writes by the possible noise, several means of protection are applied to the Flash memory.

8.1 Write protect Features

- While Power-on reset, all operations are disabled and no instruction is recognized.
- An internal time delay of tPUW can protect the data against inadvertent changes while the power supply is outside the operating specification. This includes the Write Enable, Page program, Sector Erase, Block Erase, Chip Erase, Write Security Register and the Write Status Register instructions.
- For data changes, Write Enable instruction must be issued to set the Write Enable Latch (WEL) bit to "0". Power-up, Completion of Write Disable, Write Status Register, Page program, Sector Erase, Block Erase and Chip Erase are subjected to this condition.
- Using setting the Status Register protect (SRP) and Block protect (SEC, TB, BP2, BP1, and BP0) bits a portion of memory can be configured as reading only called software protection.
- Write Protect (/WP) pin can control to change the Status Register under hardware control.
- The Deep Power Down mode provides extra software protection from unexpected data changes as all instructions are ignored under this status except for Release Deep Power-down instruction.
- One time program(OTP) mode provide protection mode from program/erase operation

9. STATUS REGISTER

The Read Status Register instruction can be used to provide status on the availability of the Flash memory array, if the device is write enabled or disabled the state of write protection and the Quad SPI setting. The Write Status Register instruction can be used to configure the devices writes protection features and Quad SPI setting. Write access to the Status Register is controlled by in some cases of the /WP pin.

S7	S6	S5	S4	S3	S2	S1	S0
SRP0	SEC	TB	BP2	BP1	BP0	WEL	BUSY
Status Register Protect 0 (Non-Volatile)	Sector Protect (Non-Volatile)	Top/Bottom Write Protect (Non-Volatile)	Block Protect (Non-Volatile)	Block Protect (Non-Volatile)	Block Protect (Non-Volatile)	Write Enable Latch	Erase or Write in Progress

Figure 5a. Status Register-1

S15	S14	S13	S12	S11	S10	S9	S8
SUS	CMP	(R)	(R)	(R)	(R)	QE	SRP1
Suspend Status	Complement Protect (Non-Volatile)	Reserved	Reserved	Reserved	Reserved	Quad Enable (Non-Volatile)	Status Register Protect 1 (Non-Volatile)

Figure 5b. Status Register-2

9.1 BUSY

BUSY is a read only bit in the status register (S0) that is set to a 1 state when the device is executing a Page Program, Erase, Write Status Register or Write Security Register instruction. During this time the device will ignore further instruction except for the Read Status Register and Erase / Program Suspend instruction (see tW, tPP, tSE, tBE1, tBE2 and tCE in AC Characteristics). When the Program, Erase, Write Status Register or Write Security Register instruction has completed, the BUSY bit will be cleared to a 0 state indicating the device is ready for further instructions.

9.2 Write Enable Latch (WEL)

Write Enable Latch (WEL) is a read only bit in the status register (S1) that is set to a 1 after executing a Write Enable instruction. The WEL status bit is cleared to a 0 when device is write disabled. A write disable state occurs upon power-up or after any of the following instructions: Write Disable, Page Program, Erase and Write Status Register.

9.3 Block Protect Bits (BP2, BP1, BP0)

The Block Protect Bits (BP2, BP1, BP0) are non-volatile read/write bits in the status register (S4, S3, and S2) that provide write protection control and status. Block protect bits can be set using the Write Status Register Instruction (see tW in AC characteristics). All, none or a portion of the memory array can be protected from Program and Erase instructions (see Status Register Memory Protection table). The factory default setting for the Block Protection Bits is 0, none of the array protected.

9.4 Top/Bottom Block protect (TB)

The Top/Bottom bit (TB) is non-volatile bits in the status register (S5) that controls if the Block Protect Bits (BP2, BP1, BP0) protect from the Top (TB=0) or the Bottom (TB=1) of the array as shown in the Status Register Memory Protection table. The factory default setting is TB=0. The TB bit can be set with the Write Status Register Instruction depending on the state of the SRP0, SRP1 and WEL bits.

9.5 Sector/Block Protect (SEC)

The Sector protect bit (SEC) is non-volatile bits in the status register (S6) that controls if the Block Protect Bits (BP2, BP1, BP0) protect 4KB Sectors (SEC=1) or 64KB Blocks (SEC=0) in the Top (TB=0) or the Bottom (TB=1) of the array as shown in the Status Register Memory protection table. The default setting is SEC=0.

9.6 Status Register protect (SRP1, SRP0)

The Status Register Protect bits (SRP1 and SRP0) are non-volatile read/write bits in the status register (S8 and S7). The SRP bits control the method of write protection: software protection, hardware protection, power supply lock-down or one time programmable (OTP) protection.

SRP1	SRP0	/WP	Status Register	Description
0	0	X	Software Protection	/WP pin no control. The register can be written to After a Write Enable instruction, WEL=1. [Factory Default]
0	1	0	Hardware Protected	When /WP pin is low the Status Register locked and can not Be written to.
0	1	1	Hardware Unprotected	When /WP pin is high the Status register is unlocked and can be written to after a Write Enable instruction, WEL=1
1	0	X	Power Supply Lock-Down	Status Register is protected and cannot be written to again until the next power-down, power-up cycle ⁽¹⁾
1	1	X	One Time Program	Status Register is permanently protected and cannot be written to.

Note:

1. When SRP1, SRP0=(1,0), a power-down, power-up cycle will change SRP1, SRP0 to(0,0) state.

9.7 Quad Enable (QE)

The Quad Enable (QE) bit is a non-volatile read/write bit in the status register (S9) that allows Quad operation. When the QE bit is set to a 0 state (factory default) the /WP pin and /Hold are enabled. When the QE pin is set to a 1 the Quad IO2 and IO3 pins are enabled.

WARNING : The QE bit should never be set to a 1 during standard SPI or Dual SPI operation if the /WP or /HOLD pins are tied directly to the power supply or ground.

9.8 Complement Protect (CMP)

The Complement Protect bit (CMP) is a non-volatile read/write bit in the status register (S14). It is used in conjunction with SEC, TB, BP2, BP1 and BP0 bits to provide more flexibility for the array protection. Once CMP is set to 1, previous array protection set by SEC, TB, BP2, BP1 and BP0 will be reversed. For instance, when CMP=0, a top 4KB sector can be protected while the rest of the array is not; when CMP=1, the top 4KB sector will become unprotected while the rest of the array become read-only. Please refer to the Status Register Memory Protection table for details. The default setting is CMP=0.

9.9 Erase/Program Suspend Status (SUS)

The Suspend Status bit (SUS) is a read only bit in the status register (S15) that is set to 1 after executing an Erase/Program Suspend (75h) instruction. The SUS status bit is cleared to 0 by Erase/Program Resume (7Ah) instruction as well as a power-down, power-up cycle.

9.10 Status Register Memory Protection (CMP = 0)

STATUS REGISTER					MEMORY PROTECTION			
SEC	TB	BP2	BP1	BP0	BLOCK(S)	ADDRESSES	DENSITY	PORTION
X	X	0	0	0	NONE	NONE	NONE	NONE
0	0	0	0	1	252 thru 255	FC0000h-FFFFFFh	256KB	Upper 1/64
0	0	0	1	0	248 thru 255	F80000h-FFFFFFh	512KB	Upper 1/32
0	0	0	1	1	240 thru 255	F00000h-FFFFFFh	1MB	Upper 1/16
0	0	1	0	0	224 thru 255	E00000h-FFFFFFh	2MB	Upper 1/8
0	0	1	0	1	192 thru 255	C00000h-FFFFFFh	4MB	Upper 1/4
0	0	1	1	0	128 thru 255	800000h-FFFFFFh	8MB	Upper 1/2
0	1	0	0	1	0 thru 3	000000h-03FFFFh	256KB	Lower 1/64
0	1	0	1	0	0 thru 7	000000h-07FFFFh	512KB	Lower 1/32
0	1	0	1	1	0 thru 15	000000h-0FFFFFFh	1MB	Lower 1/16
0	1	1	0	0	0 thru 31	000000h-1FFFFFFh	2MB	Lower 1/8
0	1	1	0	1	0 thru 63	000000h-3FFFFFFh	4MB	Lower 1/4
0	1	1	1	0	0 thru 127	000000h-7FFFFFFh	8MB	Lower 1/2
X	X	1	1	1	0 thru 255	000000h-FFFFFFh	16MB	ALL
1	0	0	0	1	255	FFF000h-FFFFFFh	4KB	U – 1/4096
1	0	0	1	0	255	FFE000h-FFFFFFh	8KB	U – 1/2048
1	0	0	1	1	255	FFC000h-FFFFFFh	16KB	U – 1/1024
1	0	1	0	X	255	FF8000h-FFFFFFh	32KB	U – 1/512
1	1	0	0	1	0	000000h-000FFFh	4KB	L – 1/4096
1	1	0	1	0	0	000000h-001FFFh	8KB	L – 1/2048
1	1	0	1	1	0	000000h-003FFFh	16KB	L – 1/1024
1	1	1	0	X	0	000000h-007FFFh	32KB	L – 1/512

Note:

1. X = don't care
2. L = Lower; U = Upper
3. If any Erase or Program instruction specifies a memory region that contains protected data portion, this instruction will be ignored.

9.11 Status Register Memory Protection (CMP = 1)

STATUS REGISTER					MEMORY PROTECTION			
SEC	TB	BP2	BP1	BP0	BLOCK(S)	ADDRESSES	DENSITY	PORTION
X	X	0	0	0	0 thru 255	000000h - FFFFFFFh	16MB	ALL
0	0	0	0	1	0 thru 251	000000h - FBFFFFh	16,128KB	Lower 63/64
0	0	0	1	0	0 and 247	000000h - F7FFFFh	15,872KB	Lower 31/32
0	0	0	1	1	0 thru 239	000000h - EFFFFFFh	15MB	Lower 15/16
0	0	1	0	0	0 thru 223	000000h - DFFFFFFh	14MB	Lower 7/8
0	0	1	0	1	0 thru 191	000000h - BFFFFFFh	12MB	Lower 3/4
0	0	1	1	0	0 thru 127	000000h - 7FFFFFFh	8MB	Lower 1/2
0	1	0	0	1	4 thru 255	040000h - FFFFFFFh	16,128KB	Upper 63/64
0	1	0	1	0	8 and 255	080000h - FFFFFFFh	15,872KB	Upper 31/32
0	1	0	1	1	16 thru 255	100000h - FFFFFFFh	15MB	Upper 15/16
0	1	1	0	0	32 thru 255	200000h - FFFFFFFh	14MB	Upper 7/8
0	1	1	0	1	64 thru 255	400000h - FFFFFFFh	12MB	Upper 3/4
0	1	1	1	0	128 thru 255	800000h - FFFFFFFh	8MB	Upper 1/2
X	X	1	1	1	NONE	NONE	NONE	NONE
1	0	0	0	1	0 thru 255	000000h - FFEFFFFh	16,380KB	L – 4095/4096
1	0	0	1	0	0 thru 255	000000h - FFDFFFFh	16,376KB	L – 2047/2048
1	0	0	1	1	0 thru 255	000000h - FFBFFFFh	16,368KB	L – 1023/1024
1	0	1	0	X	0 thru 255	000000h - FF7FFFFh	16,352KB	L – 511/512
1	1	0	0	1	0 thru 255	001000h - FFFFFFFh	16,380KB	U – 4095/4096
1	1	0	1	0	0 thru 255	002000h - FFFFFFFh	16,376KB	U – 2047/2048
1	1	0	1	1	0 thru 255	004000h - FFFFFFFh	16,368KB	U – 1023/1024
1	1	1	0	X	0 thru 255	008000h - FFFFFFFh	16,352KB	U – 511/512

Note:

1. X = don't care
2. L = Lower; U = Upper
3. If any Erase or Program instruction specifies a memory region that contains protected data portion, this instruction will be ignored.

10. INSTRUCTIONS

The SPI instruction set of the AS25F1128MQ consists of thirty eight basic instructions and the QPI instruction set of the AS25F1128MQ consists of thirty one basic instructions that are fully controlled through the SPI bus (see Instruction Set table). Instructions are initiated with the falling edge of Chip Select (/CS). The first byte of data clocked into the input pins (DI or IO [3:0]) provides the instruction code. Data on the DI input is sampled on the rising edge of clock with most significant bit (MSB) first.

Instructions are completed with the rising edge of edge /CS. Clock relative timing diagrams for each instruction are included in figures 6 through 43. All read instructions can be completed after any clocked bit. However, all instructions that Write, Program or Erase must complete on a byte (/CS driven high after a full 8-bit have been clocked) otherwise the instruction will be terminated. This feature further protects the device from inadvertent writes. Additionally, while the memory is being programmed or erased, or when the Status Register is being written, all instructions except for Read Register will be ignored until the program or erase cycle has completed.

10.1 Manufacturer and Device Identification

		ID code	Instruction
Manufacturer ID	Alliance Memory	52h	90h, 92h, 94h, 9Fh
Device ID	AS25F1128MQ	17h	90h, 92h, 94h, ABh
Memory Type ID	SPI / QPI	42h	9Fh
Capacity Type ID	128M	18h	9Fh

10.2 Instruction Set Table 1 (SPI instruction)⁽¹⁾

INSTRUCTION NAME	BYTE 1	BYTE 2	BYTE 3	BYTE 4	BYTE 5	BYTE 6
(CLOCK NUMBER)	(0 – 7)	(8 - 15)	(16 - 23)	(24 - 31)	(32 - 39)	(40 - 47)
Write Enable	06h					
Write Enable For Volatile Status Register	50h					
Write Disable	04h					
Read Status Register-1	05h	(SR7-SR0) ⁽²⁾				
Read Status Register-2	35h	(SR15-SR8) ⁽²⁾				
Write Status Register-1	01h	(SR7-SR0)	(SR15-SR8)			
Write Status Register-2	31h	(SR15-SR8)				
Read Data	03h	A23-A16	A15-A8	A7-A0	(D7-D0)	
Fast Read Data	0Bh	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Page Program	02h	A23-A16	A15-A8	A7-A0	(D7-D0) ⁽³⁾	
Enable QPI	38h					
Sector Erase(4KB)	20h	A23-A16	A15-A8	A7-A0		
Block Erase(32KB)	52h	A23-A16	A15-A8	A7-A0		
Block Erase(64KB)	D8h	A23-A16	A15-A8	A7-A0		
Chip Erase	60h/C7h					
Erase/Program Suspend	75h					
Erase/Program Resume	7Ah					
Deep Power-down	B9h					
Release Deep power down/ Device ID ⁽⁴⁾	ABh	Dummy	dummy	dummy	(ID7-ID0) ⁽²⁾	
Read Manufacturer/ Device ID ⁽⁴⁾	90h	00h	00h	00h or 01h	(MID7-MID0)	(DID7-DID0)
Read JEDEC ID	9Fh	(MID7-MID0) Manufacturer	(D7-D0) Memory Type	(D7-D0) Capacity Type		
Reset Enable	66h					
Reset	99h					
Enter Secured OTP	B1h					
Exit Secured OTP	C1h					
Read Security Register	2Bh	(SC7-SC0) ⁽¹⁰⁾				
Write Security Register	2Fh					
Read Serial Flash Discovery Parameter	5Ah	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)

10.3 Instruction Set Table 2 (Dual SPI Instruction)

(CLOCK NUMBER) INSTRUCTION NAME	(0 - 7)	(8 - 15)	(16 - 23)	(24 - 31)	(32 - 39)	(40 - 47)
Fast Read Dual Output	3Bh	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽⁶⁾
Fast Read Dual I/O	BBh	A23-A8 ⁽⁵⁾	A7-A0, M7-M0 ⁽⁵⁾	(D7-D0, ...) ⁽⁶⁾		
Read Dual Manufacture/ Device ID ⁽⁴⁾	92h	0000h	(00h, xxxx) or (01h, xxxx)	(MID7-MID0) (DID7-DID0) ⁽⁶⁾		

10.4 Instruction Set Table 3 (Quad SPI Instruction)

(CLOCK NUMBER) INSTRUCTION NAME	(0 - 7)	(8 - 15)	(16 - 23)	(24 - 31)	(32 - 39)	(40 - 47)
Fast Read Quad Output	6Bh	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽⁸⁾
Fast Read Quad I/O	EBh	A23-A0, M7-M0 ⁽⁷⁾	(xxxx, D7-D0,...) ⁽⁹⁾	(D7-D0, ...) ⁽⁸⁾		
Quad Page Program	33h	A23-A0 (D7-D0, ...) ⁽⁸⁾				
Read Quad Manufacture/Device ID ⁽⁴⁾	94h	(00_0000h, xx) or (00_0001h, xx)	(xxxx, MID7-MID0) (xxxx, DID7-DID0) ⁽⁹⁾			
Word Read Quad I/O	E7h	A23-A0, M7-M0 ⁽⁷⁾	(xx, D7-D0..)	(D7-D0) ⁽⁸⁾		
Set Burst with Wrap	77h	xxxxxx, W6-W4 ⁽⁷⁾				

10.5 Instruction Set Table 4 (QPI instruction)

INSTRUCTION NAME		BYTE 1	BYTE 2	BYTE 3	BYTE 4	BYTE 5	BYTE 6	BYTE 7	BYTE 8	BYTE 9
(CLOCK NUMBER)		(0 , 1)	(2 , 3)	(4 , 5)	(6 , 7)	(8 , 9)	(10 , 11)	(12 , 13)	(14 , 15)	(16 , 17)
Write Enable		06h								
Write Enable for Volatile Status Register		50h								
Write Disable		04h								
Read Status Register-1		05h	(SR7-SR0) ⁽²⁾							
Read Status Register-2		35h	(SR15-SR8) ⁽²⁾							
Write Status Register-1 ⁽⁵⁾		01h	(SR7-SR0)	(SR15-SR8)						
Write Status Register-2		31h	(SR15-SR8)							
Fast Read Data	>80MHz	0Bh	A23-A16	A15-A8	A7-A0	dummy	dummy	(D7-D0)		
	>108MHz		A23-A16	A15-A8	A7-A0	dummy	dummy	dummy	(D7-D0)	
	>133MHz		A23-A16	A15-A8	A7-A0	dummy	dummy	dummy	dummy	(D7-D0)
Page Program		02h	A23-A16	A15-A8	A7-A0	(D7-D0) ⁽³⁾				
Sector Erase(4KB)		20h	A23-A16	A15-A8	A7-A0					
Block Erase(32KB)		52h	A23-A16	A15-A8	A7-A0					
Block Erase(64KB)		D8h	A23-A16	A15-A8	A7-A0					
Chip Erase		60h/ C7h								
Erase/Program Suspend		75h								
Erase/Program Resume		7Ah								
Deep Power-down		B9h								
Release Deep power down		ABh								
Read Manufacturer/ Device ID ⁽⁴⁾		90h	00h	00h	00h or 01h	(MID7-MID0)	(DID7-DID0)			
Read JEDEC ID ⁽⁴⁾		9Fh	(MID7-MID0) Manufact urer	(D7-D0) Memory Type	(D7-D0) Capacity Type					
Enter Security		B1h								
Exit Security		C1h								
Read Security Register		2Bh	(SC7-SC0) ⁽¹⁰⁾							
Write Security Register		2Fh								
Fast Read Quad I/O	>80MHz	EBh	A23-A16	A15-A8	A7-A0	(M7-M0)	dummy	(D7-D0)		
	>108MHz		A23-A16	A15-A8	A7-A0	(M7'-M0)	dummy	dummy	(D7-D0)	
	>133MHz		A23-A16	A15-A8	A7-A0	(M7'-M0)	dummy	dummy	dummy	(D7-D0)
Reset Enable		66h								
Reset		99h								

Disable QPI		FFh								
Burst Read with Wrap	>80MHz	0Ch	A23-A16	A15-A8	A7-A0	dummy	dummy	(D7-D0)		
	>108MHz		A23-A16	A15-A8	A7-A0	dummy	dummy	dummy	(D7-D0)	
	>133MHz		A23-A16	A15-A8	A7-A0	dummy	dummy	dummy	dummy	(D7-D0)
Set Read Parameter		C0h	P7-P0							
Quad Page Program		33h	A23-A16	A15-A8	A7-A0	(D7-D0)				

Notes:

- Data bytes are shifted with Most Significant Bit first. Byte fields with data in parenthesis “()” indicate data being read from the device on the IO pin.
- SR = status register,
The Status Register contents and Device ID will repeat continuously until /CS terminates the instruction.
- At least one byte of data input is required for Page Program, Quad Page Program and Program Security Register, up to 256 bytes of data input. If more than 256 bytes of data are sent to the device, the addressing will wrap to the beginning of the page and overwrite previously sent data.
- See Manufacturer and Device Identification table for Device ID information.
- Dual Input Address
 IO0 = A22, A20, A18, A16, A14, A12, A10, A8, A6, A4, A2, A0, M6, M4, M2, M0
 IO1 = A23, A21, A19, A17, A15, A13, A11, A9, A7, A5, A3, A1, M7, M5, M3, M1
- Dual Output data
 IO0 = (D6, D4, D2, D0)
 IO1 = (D7, D5, D3, D1)
- Quad Input Address
 IO0 = A20, A16, A12, A8, A4, A0, M4, M0
 IO1 = A21, A17, A13, A9, A5, A1, M5, M1
 IO2 = A22, A18, A14, A10, A6, A2, M6, M2
 IO3 = A23, A19, A15, A11, A7, A3, M7, M3

Set Burst with Wrap Input	
IO0 = x, x, x, x, x, x, W4,	x
IO1 = x, x, x, x, x, x, W5,	x
IO2 = x, x, x, x, x, x, W6,	x
IO3 = x, x, x, x, x, x, x	x
- Quad Input/ Output Data
 IO0 = (D4, D0...)
 IO1 = (D5, D1...)
 IO2 = (D6, D2...)
 IO3 = (D7, D3...)
- Fast Read Quad I/O Data Output
 IO0 = (x, x, x, x, D4, D0...)
 IO1 = (x, x, x, x, D5, D1...)
 IO2 = (x, x, x, x, D6, D2...)
 IO3 = (x, x, x, x, D7, D3...)
- SC = security register

10.6 Write Enable (06h)

Write Enable instruction is for setting the Write Enable Latch (WEL) bit in the Status Register. The WEL bit must be set prior to every Program, Erase and Write Status Register instruction. To enter the Write Enable instruction, /CS goes low prior to the instruction "06h" into Data Input (DI) pin on the rising edge of CLK, and then driving /CS high.

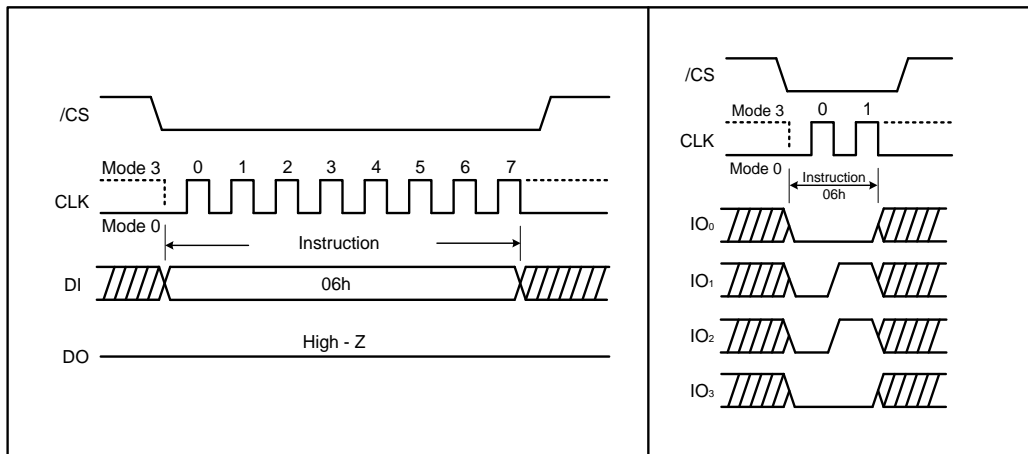


Figure 6. Write Enable Instruction for SPI Mode (left) and QPI Mode (right)

10.7 Write Enable for Volatile Status Register (50h)

This gives more flexibility to change the system configuration and memory protection schemes quickly without waiting for the typical non-volatile bit write cycles or affecting the endurance of the Status Register non-volatile bits. To write the volatile values into the Status Register bits, the Write Enable for Volatile Status Register (50h) instruction must be issued prior to a Write Status Register (01h) instruction. Write Enable for Volatile Status Register instruction (Figure 7) will not set the Write Enable Latch (WEL) bit. Once Write Enable for Volatile Status Register is set, a Write Enable instruction should not have been issued prior to setting Write Status Register instruction (01h or 31h).

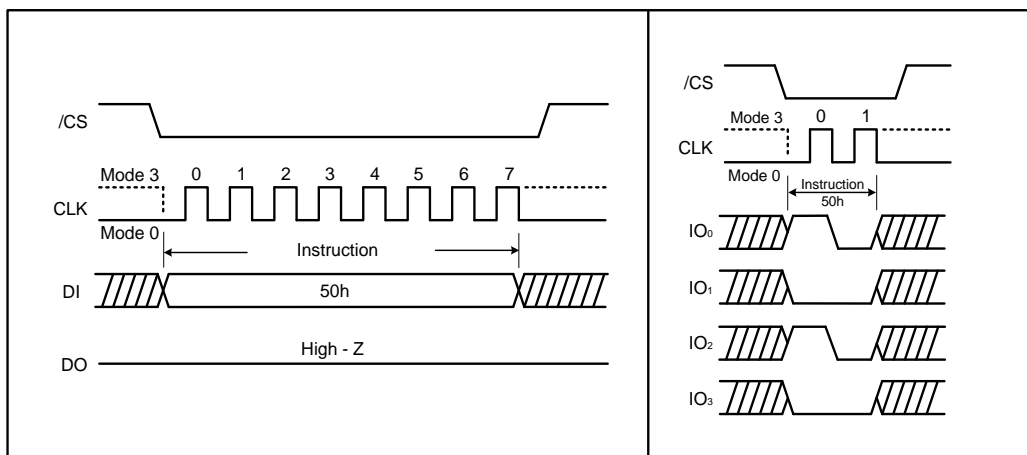


Figure 7. Write Enable for Volatile Status Register Instruction for SPI Mode (left) and QPI Mode (right)

10.8 Write Disable (04h)

The Write Disable instruction is to reset the Write Enable Latch (WEL) bit in the Status Register. To enter the Write Disable instruction, /CS goes low prior to the instruction "04h" into Data Input (DI) pin on the rising edge of CLK, and then driving /CS high. WEL bit is automatically reset write-disable status of "0" after Power-up and upon completion of the every Program, Erase and Write Status Register instructions.

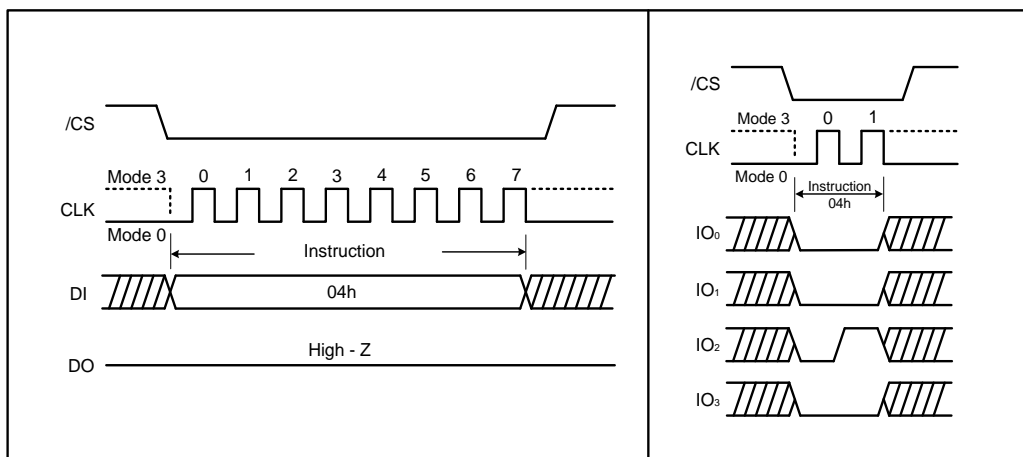


Figure 8. Write Disable Instruction for SPI Mode (left) and QPI Mode (right)

10.9 Read Status Register-1 (05h) and Read Status Register-2 (35h)

The Read Status Register instructions are to read the Status Register. The Read Status Register can be read at any time (even in program/erase/write Status Register and Write Security Register condition). It is recommended to check the BUSY bit before sending a new instruction when a Program, Erase, Write Status Register or Write Status Register operation is in progress.

The instruction is entered by driving /CS low and sending the instruction code "05h" for Status Register-1 or "35h" for Status Register-2 into the DI pin on the rising edge of CLK. The status register bits are then shifted out on the DO pin at the falling edge of CLK with most significant bit (MSB) first as shown in (figure 9). The Status Register can be read continuously. The instruction is completed by driving /CS high.

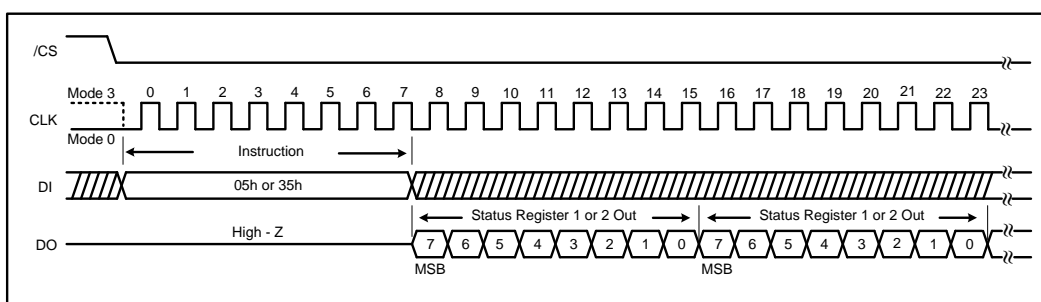


Figure 9a. Read Status Register Instruction (SPI Mode)

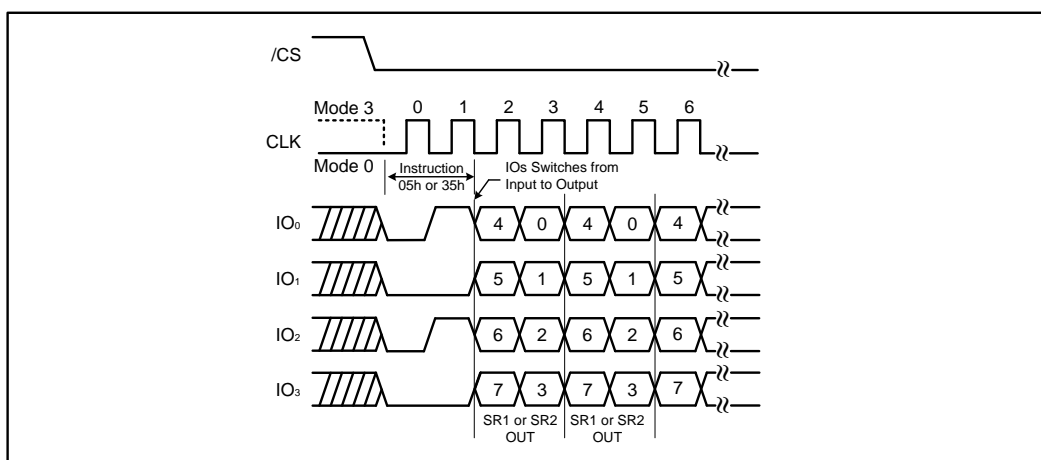


Figure 9b. Read Status Register Instruction (QPI Mode)

10.10 Write Status Register (01h)

The Write Status Register instruction is to write only non-volatile Status Register-1 bits (SRP0, SEC, TB, BP2, BP1 and BP0) and Status Register-2 bits (CMP, QE and SRP1). All other Status Register bit locations are read-only and will not be affected by the Write Status Register instruction.

A Write Enable instruction must previously have been issued prior to setting Write Status Register Instruction (Status Register bit WEL must equal 1). Once write is enabled, the instruction is entered by driving /CS low, sending the instruction code, and then writing the status register data byte as illustrated in figure 10.

The /CS pin must be driven high after the eighth or sixteenth bit of data that is clocked in. If this is not done the Write Status Register instruction will not be executed. If /CS is driven high after the eighth clock, the CMP QE and SRP1 bits will be cleared to 0. After /CS is driven high, the self-timed Write Status Register cycle will commence for a time duration of t_w (See AC Characteristics).

While the Write Status Register cycle is in progress, the Read Status Register instruction may still be accessed to check the status of the BUSY bit. The BUSY bit is a 1 during the Write Status Register cycle and a 0 when the cycle is finished and ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in Status Register will be cleared to 0.

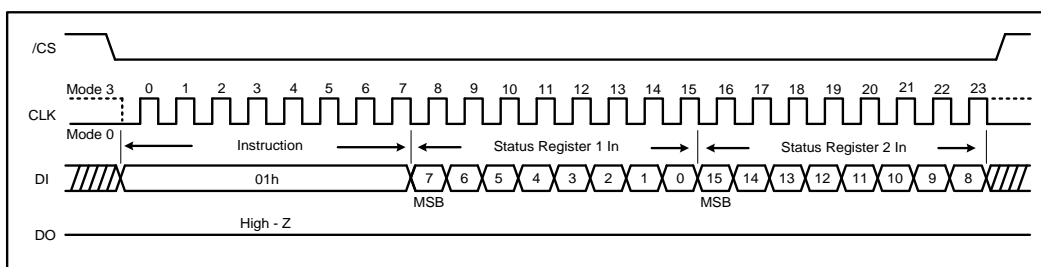


Figure 10a. Write Status Register Instruction (SPI Mode)

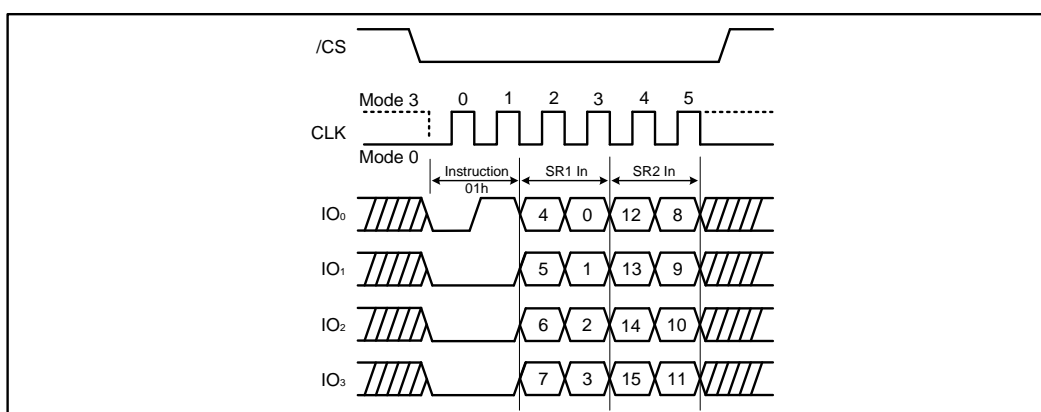


Figure 10b. Write Status Register Instruction (QPI Mode)

10.11 Write Status Register-2 (31h)

The Write Status Register-2 instruction is to write only non-volatile Status Register-2 bits (CMP, QE and SRP1).

A Write Enable instruction must previously have been issued prior to setting Write Status Register Instruction (Status Register bit WEL must equal 1). Once write is enabled, the instruction is entered by driving /CS low, sending the instruction code, and then writing the status register data byte as illustrated in figure 11.

Using Write Status Register-2 (31h) instruction, software can individually access each one-byte status registers via different instructions.

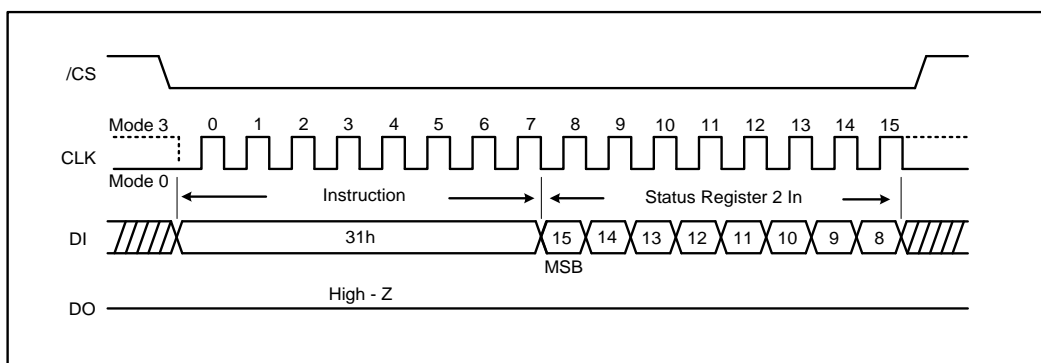


Figure 11a. Write Status Register-2 Instruction (SPI Mode)

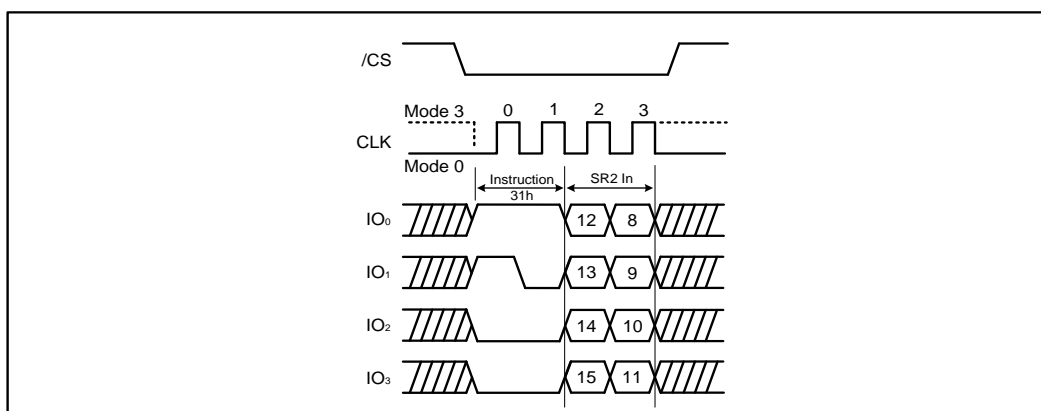


Figure 11b. Write Status Register-2 Instruction (QPI Mode)

10.12 Read Data (03h)

The Read Data instruction is to read data out from the device. The instruction is initiated by driving the /CS pin low and then sending the instruction code "03h" with following a 24-bit address (A23-A0) into the DI pin. After the address is received, the data byte of the addressed memory location will be shifted out on the DO pin at the falling edge of CLK with most significant bit (MSB) first. The address is automatically incremented to the next higher address after byte of data is shifted out allowing for a continuous stream of data. This means that the entire memory can be accessed with a single instruction as long as the clock continues. The instruction is completed by driving /CS high. The Read Data instruction sequence is shown in (figure 12). If a Read Data instruction is issued while an Erase, Program or Write Status Register cycle is in process (BUSY=1) the instruction is ignored and will not have any effects on the current cycle. The Read Data instruction allows clock rates from D.C to a maximum of f_R (see AC Electrical Characteristics).

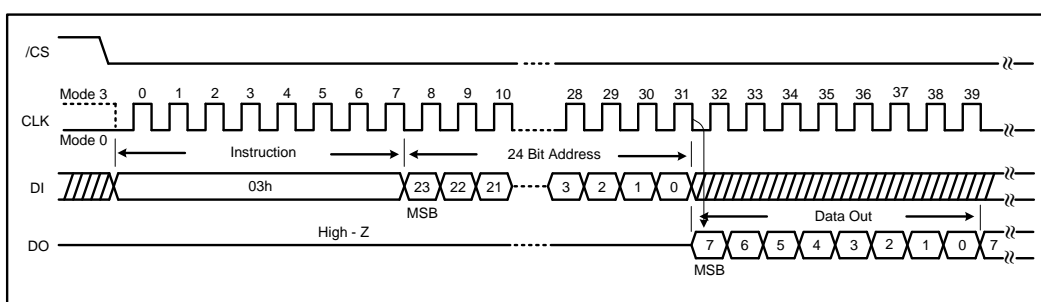


Figure 12. Read Data Instruction

10.13 Fast Read (0Bh)

The Fast Read instruction is high speed reading mode that it can operate at the highest possible frequency of F_R . The address is latched on the rising edge of the CLK. After the 24-bit address, this is accomplished by adding "dummy" clocks as shown in (figure 13). The dummy clocks means the internal circuits require time to set up the initial address. During the dummy clocks, the data value on the DO pin is a "don't care". Data of each bit shifts out on the falling edge of CLK.

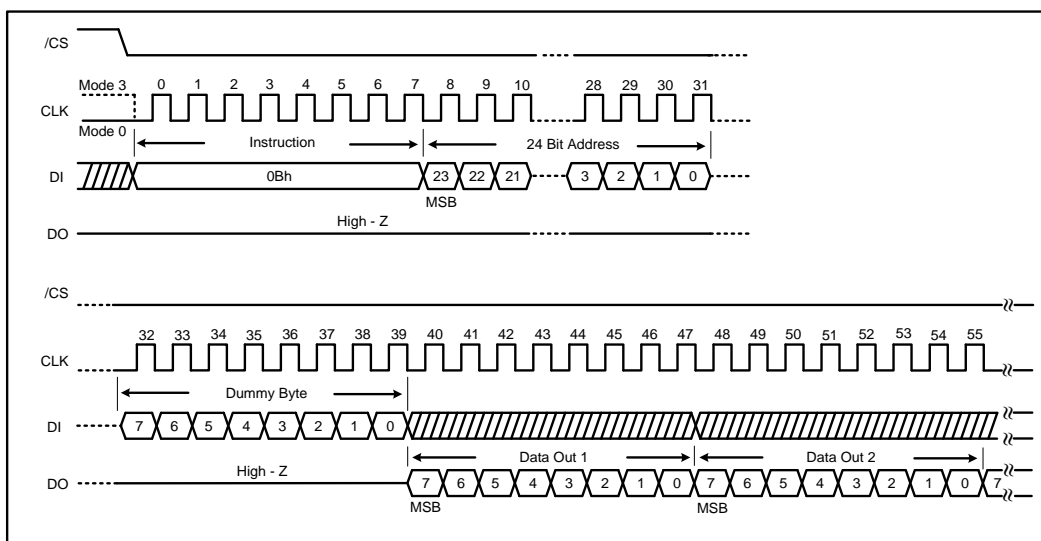


Figure 13a. Fast Read Instruction (SPI Mode)

Fast Read in QPI Mode

When QPI mode is enabled, the number of dummy clock is configured by the “Set Read Parameters (C0h)” instruction to accommodate wide range applications with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bit P[4] and P[5] setting, the number of dummy clocks can be configured as either 4, or 6 or 8. The default number of dummy clocks upon power up or after a Reset instruction is 4. (Please refer to figure 13b, 13c, 13d).

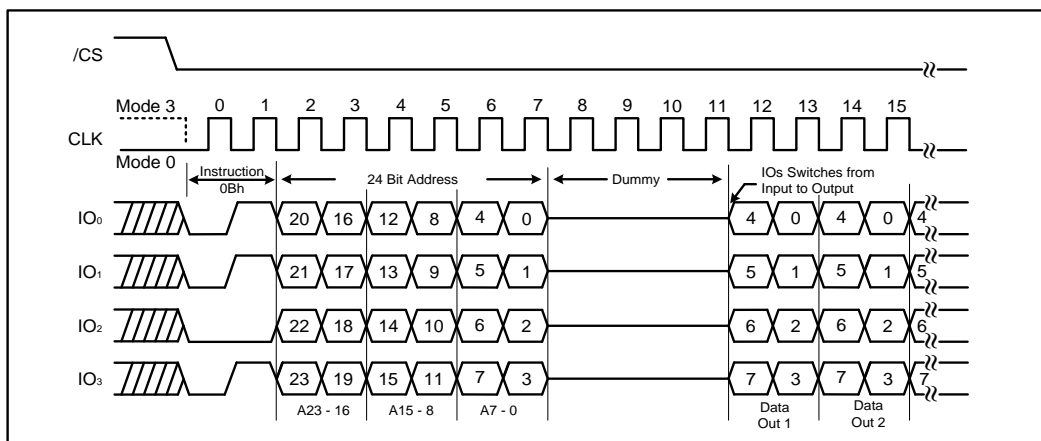


Figure 13b. Fast Read instruction (QPI Mode, 80MHz)

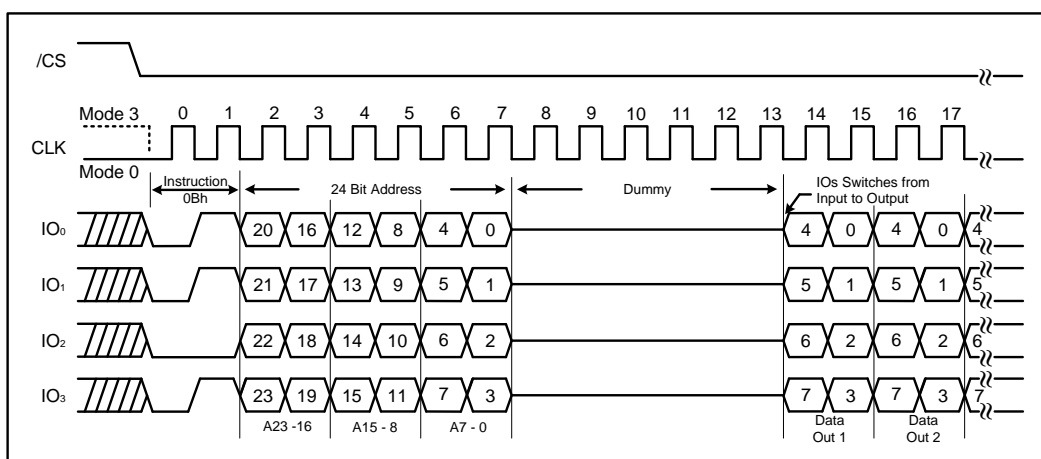


Figure 13c. Fast Read instruction (QPI Mode, 108MHz)

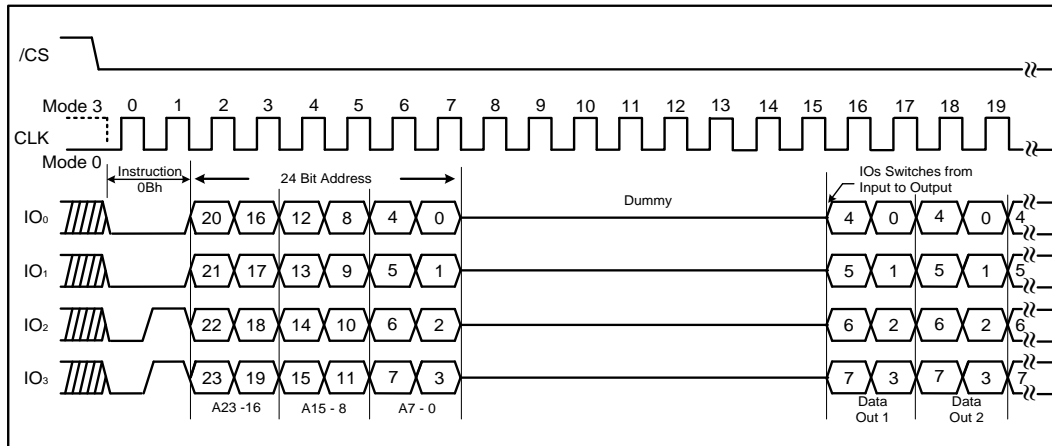


Figure 13d. Fast Read instruction (QPI Mode, 133MHz)

10.14 Fast Read Dual Output (3Bh)

By using two pins (IO₀ and IO₁, instead of just IO₀), The Fast Read Dual Output instruction allows data to be transferred from the AS25F1128MQ at twice the rate of standard SPI devices. The Fast Read Dual Output instruction is ideal for quickly downloading code from Flash to RAM upon power-up or for application that cache code-segments to RAM for execution.

The Fast Read Dual Output instruction can operate at the highest possible frequency of F_R (see AC Electrical Characteristics). After the 24-bit address, this is accomplished by adding eight “dummy” clocks as shown in (figure 14). The dummy clocks allow the internal circuits additional time for setting up the initial address. During the dummy clocks, the data value on the DO pin is a “don’t care”. However, the IO₀ pin should be high-impedance prior to the falling edge of the first data out clock.

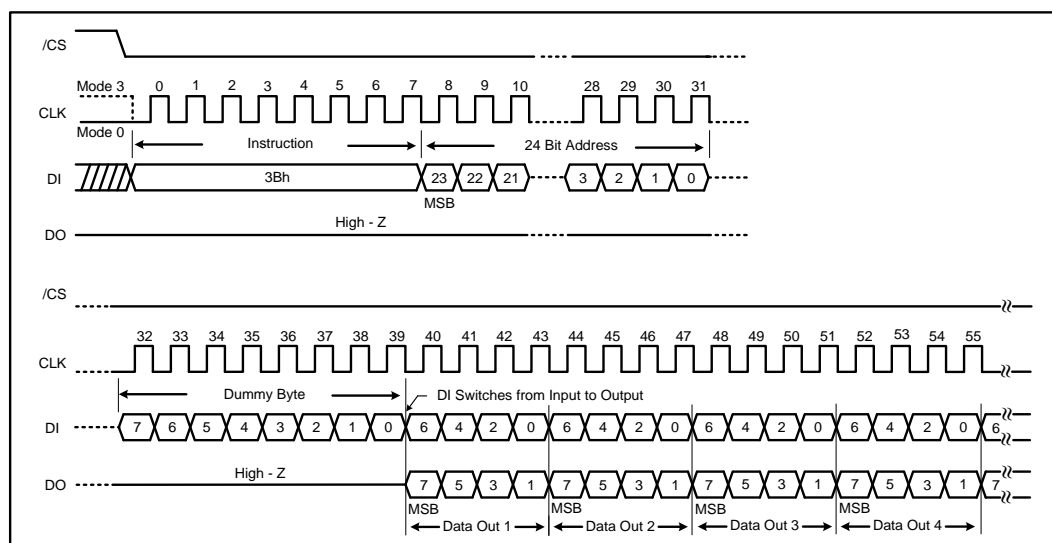


Figure14. Fast Read Dual Output instruction (SPI Mode)

A Quad enable of Status Register-2 must be executed before the device will accept the Fast Read Quad Output instruction (Status Register bit QE must equal 1).

The diagram illustrates the timing for Mode 0 and Mode 3 of the 74VHC163 4-bit counter. The /CS signal is active-low. The CLK signal is a clock. The IO signals are IO₀, IO₁, IO₂, and IO₃.

Mode 0: Used for instruction loading and address output. The instruction 6Bh is loaded into the counter. The 24-bit address is output on IO₀ to IO₃. The address is split into two 12-bit segments: 23-12 and 11-0.

Mode 3: Used for data output. The data is output on IO₀ to IO₃. The data is split into two 4-bit segments: 4-1 and 0-3.

The diagram shows the following data values:

IO ₀	IO ₁	IO ₂	IO ₃
4	0	4	0
5	1	5	1
6	2	6	2
7	3	7	3

Figure 15. Fast Read Quad Output instruction (SPI Mode)

The Fast Read Dual I/O instruction reduces cycle overhead through double access using two IO pins: IO₀ and IO₁.

The Fast Read Dual I/O instruction can further reduce cycle overhead through setting the Mode bits (M7-0) after the input Address bits (A23-0). The upper nibble of the Mode (M7-4) controls the length of the next Fast Read Dual I/O instruction through the inclusion or exclusion of the first byte instruction code. The lower nibble bits of the Mode (M3-0) are don't care ("X"). However, the IO pins should be high-impedance prior to the falling edge of the first data out clock.

The timing diagram for the 74VHC04BQ1 in Mode 3 shows the following signals and their behavior over 40 clock cycles:

- /CS:** Active low signal, goes low at cycle 0 and remains low until cycle 39.
- CLK:** Periodic square wave clock signal, cycles 0 to 39.
- DI:** Input signal. It is high-Z until cycle 32, then switches from input to output. The input data is BBh (22, 20, 18, 16, 14, 12, 10, 8, 6, 4, 2, 0) for cycles 0-15, and the output data is 6, 4, 2, 0 for cycles 16-31. The output data is 7, 5, 3, 1 for cycles 32-39.
- DO:** Output signal. It is high-Z until cycle 32, then outputs the data from DI. The output data is 23, 21, 19, 17, 15, 13, 11, 9, 7, 5, 3, 1 for cycles 0-15, and the output data is 7, 5, 3, 1 for cycles 16-31. The output data is 7, 5, 3, 1 for cycles 32-39.

The diagram is divided into four sections:

- Instruction:** Cycles 0 to 15. DI is high-Z. DO is high-Z.
- 24 Bit Address:** Cycles 16 to 31. DI is high-Z. DO is high-Z.
- Data Out 1:** Cycles 32 to 39. DI is high-Z. DO outputs data 7, 5, 3, 1.
- Data Out 2:** Cycles 40 to 47. DI is high-Z. DO outputs data 7, 5, 3, 1.

Figure 16a. Fast Read Dual I/O Instruction (initial instruction or previous M7-0 \neq Axx)

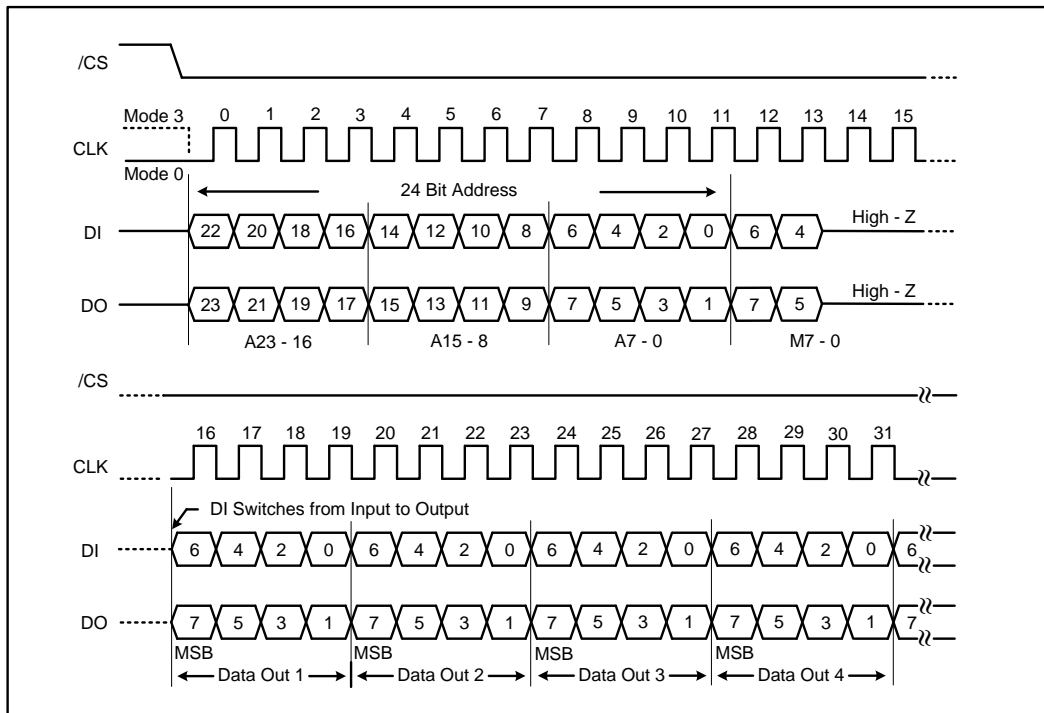


Figure 16b. Fast Read Dual I/O Instruction (previous M7-0= Axh)

10.17 Fast Read Quad I/O (EBh)

The Fast Read Quad I/O instruction reduces cycle overhead through quad access using four IO pins: IO₀, IO₁, IO₂, and IO₃. The Quad Enable bit (QE) of Status Register-2 must be set to enable the Fast read Quad I/O Instruction.

Continuous read mode

The Fast Read Quad I/O instruction can further reduce instruction overhead through setting the Mode bits (M7-0) with following the input Address bits (A23-0), as shown in (figure 17a). The upper nibble of the Mode (M7-4) controls the length of the next Fast Read Quad I/O instruction through the inclusion or exclusion of the first byte instruction code. The lower nibble bits of the Mode (M3-0) are don't care ("X"). However, the IO pins should be high-impedance prior to the falling edge of the first data out clock.

If the Mode bits (M7-0) equal "Ax" hex, then the next Fast Read Quad I/O instruction (after /CS is raised and then lowered) does not require the EBh instruction code, as shown in (figure 17b). This reduces the instruction sequence by eight clocks and allows the address to be immediately entered after /CS is asserted low. If the Mode bits (M7-0) are any value other than "Ax" hex, the next instruction (after /CS is raised and then lowered) requires the first byte instruction code, thus retuning normal operation. A Mode Bit Reset can be used to reset Mode Bits (M7-0) before issuing normal instructions.

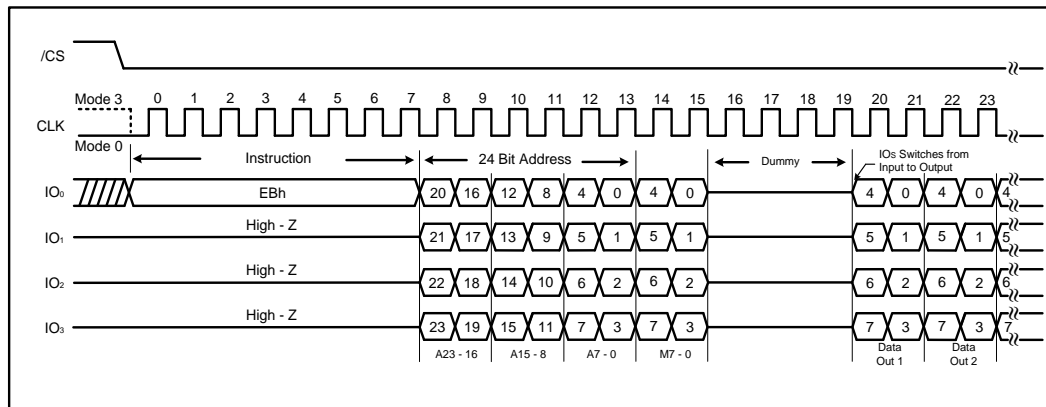


Figure 17a. Fast Read Quad I/O Instruction (Initial instruction or previous M7-0 ≠ Axh, SPI mode)

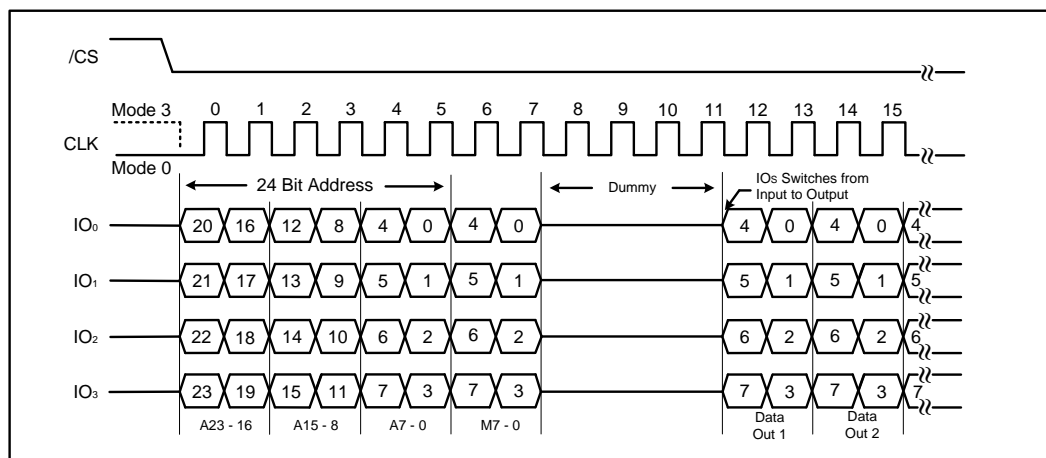


Figure 17b. Fast Read Quad I/O Instruction (previous M7-0 = Axh, SPI mode)

Wrap Around in SPI mode

The Fast Read Quad I/O instruction can also be used to access specific portion within a page by issuing a “Set Burst with Wrap” (77h) instruction prior Fast Read Quad I/O (EBh) instruction. The “Set Burst with Wrap” (77h) instruction can either enable or disable the “Wrap Around” feature for the following Fast Read Quad I/O instruction.

When “Wrap Around” is enabled, the data being accessed can be limited to an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the instruction, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around to the beginning boundary automatically until /CS is pulled high to terminate the instruction.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read instructions. (Please refer to 10.35 Set Burst with Wrap).

Fast Read Quad I/O in QPI mode

When QPI mode is enabled, the number of dummy clocks is configured by the “Set Read Parameters (C0h)” instruction to accommodate a wide range applications with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P [4] and P [5] setting, the number of dummy clocks can be configured as either 4 or 6 or 8. The default number of dummy clocks upon power up or after a Reset (99h) instruction is 4.

“Continuous Read Mode” feature is also available in QPI mode for Fast Read Quad I/O instruction. In QPI mode, the “Continuous Read Mode” bits M7-0 are also considered as dummy clocks. In the default setting, the data output will follow the Continuous Read Mode bits immediately.

“Wrap Around” feature is not available in QPI mode for Fast Read Quad I/O instruction. To perform a read operation with fixed data length wrap around in QPI mode, a “Burst Read with Wrap” (0Ch) instruction must be used. (Please refer to 10.36 Burst Read with Wrap).

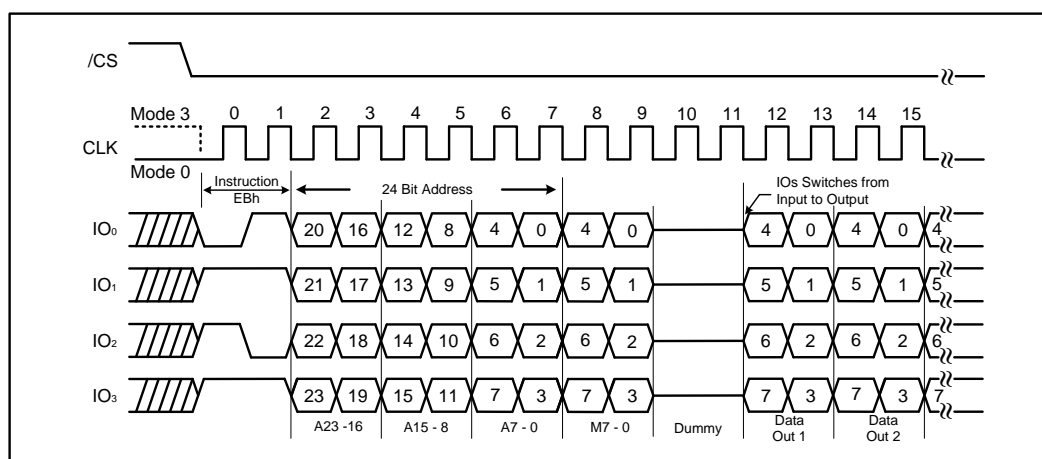
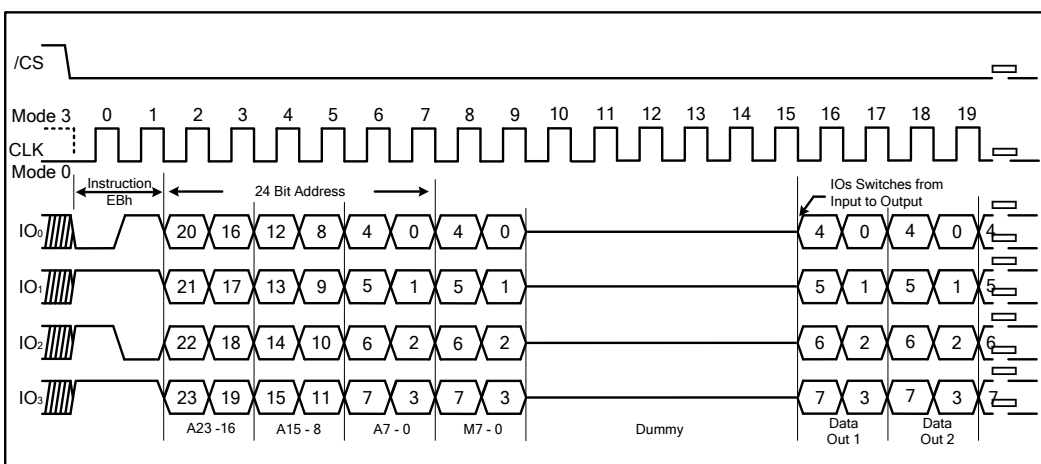
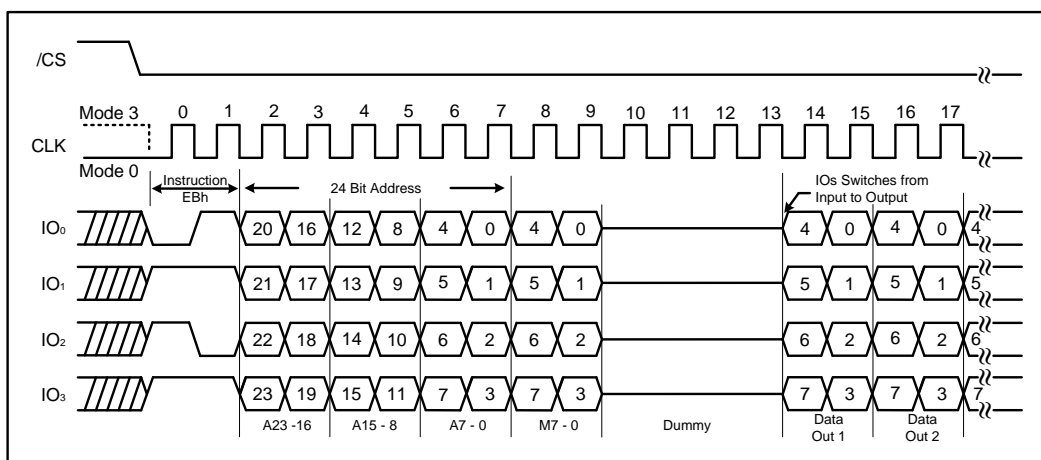


Figure 17c. Fast Read Quad I/O Instruction
 (Initial instruction or previous M7-0 ≠ Axx, QPI mode, 80MHz)



10.18 Page Program (02h)

The Page Program instruction is for programming the memory to be “0”. A Write Enable instruction must be issued before the device accept the Page Program Instruction (Status Register bit WEL= 1). After the Write Enable (WREN) instruction has been decoded, the device sets the Write Enable Latch (WEL). The instruction is entered by driving the /CS pin low and then sending the instruction code “02h” with following a 24-bits address (A23-A0) and at least one data byte, into the DI pin. The /CS pin must be driven low for the entire time of the instruction while data is being sent to the device. (Please refer to figure 18).

If an entire 256 byte page is to be programmed, the last address byte (the 8 least significant address bits) should be set to 0. If the last address byte is not zero, and the number of clocks exceeds the remaining page length, the addressing will wrap to the beginning of the page. In some cases, less than 256 bytes (a partial page) can be programmed without having any effect on other bytes within the same page. One condition to perform a partial page program is that the number of clocks cannot exceed the remaining page length. If more than 256 bytes are sent to the device the addressing will wrap to the beginning of the page and overwrite previously sent data.

The /CS pin must be driven high after the eighth bit of the last byte has been latched. If this is not done the Page Program instruction will not be executed. After /CS is driven high, the self-timed Page Program instruction will commence for a time duration of tPP (See AC Characteristics). While the Page Program cycle is in progress, the Read Status Register instruction may still be accessed for checking the status of the BUSY bit. The BUSY bit is a 1 during the Page Program cycle and becomes a 0 when the cycle is finished and the device is ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in the Status Register is cleared to 0. The Page Program instruction will not be executed if the addressed page is protected by the Protect (CMP, SEC, TB, BP2, BP1 and BP0) bits.

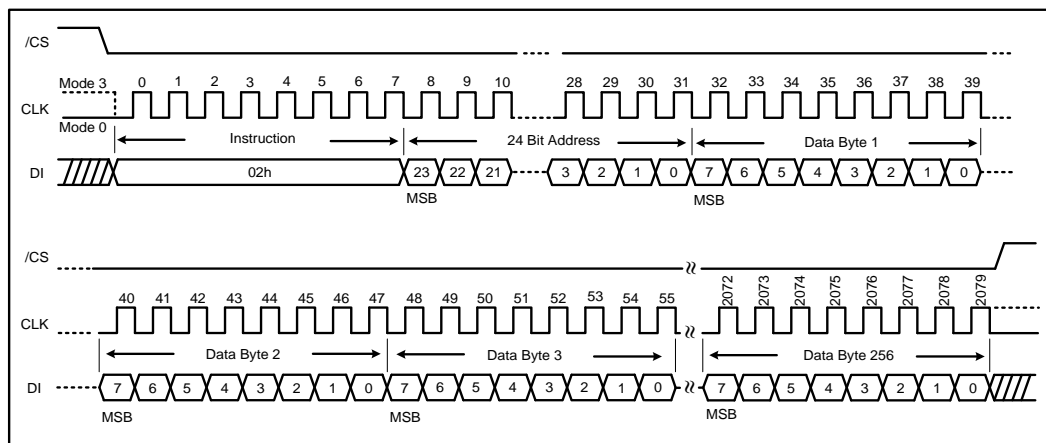


Figure 18a. Page Program Instruction (SPI Mode)

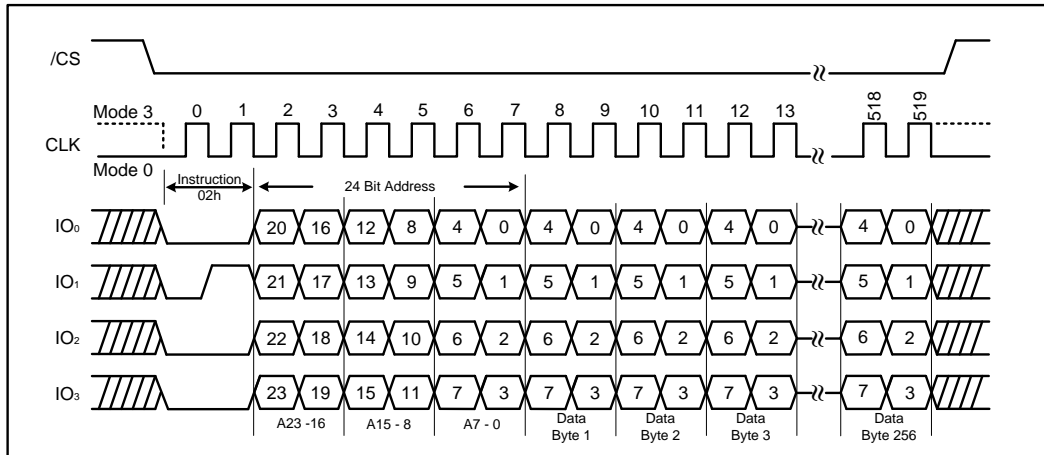


Figure 18b. Page Program Instruction (QPI Mode)

10.19 Quad Page Program (33h)

The Quad Page Program instruction is to program the memory as being "0" at previously erased memory areas. The Quad Page Program takes four pins: IO₀, IO₁, IO₂ and IO₃ as address and data input, which can improve programmer performance and the effectiveness of application of lower clock less than 5MHz. System using faster clock speed will not get more benefit for the Quad Page Program as the required internal page program time is far more than the time data clock-in.

To use Quad Page Program, the Quad Enable bit must be set, A Write Enable instruction must be executed before the device will accept the Quad Page Program instruction (Status Register-1, WEL=1). The instruction is initiated by driving the /CS pin low then sending the instruction code "33h" with following a 24-bit address (A23-A0) and at least one data, into the IO pins. The /CS pin must be held low for the entire length of the instruction while data is being sent to the device. All other functions of Quad Page Program are perfectly same as standard Page Program. (Please refer to figure 19).

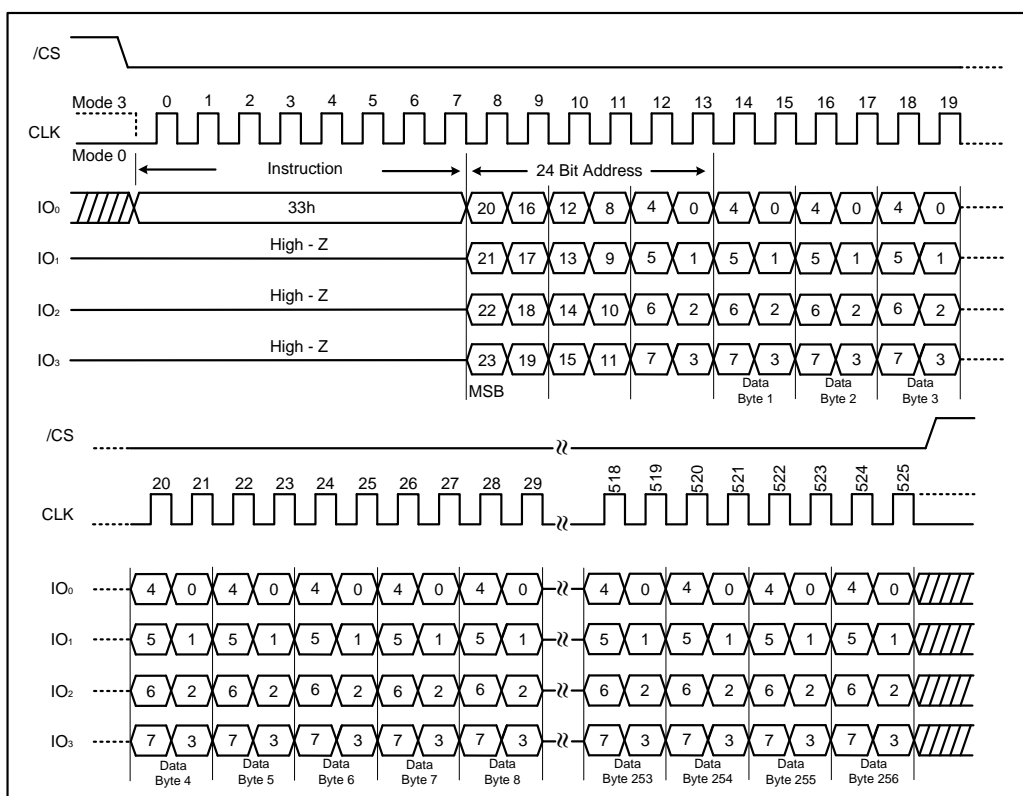


Figure 19a. Quad Page Program Instruction (SPI mode)

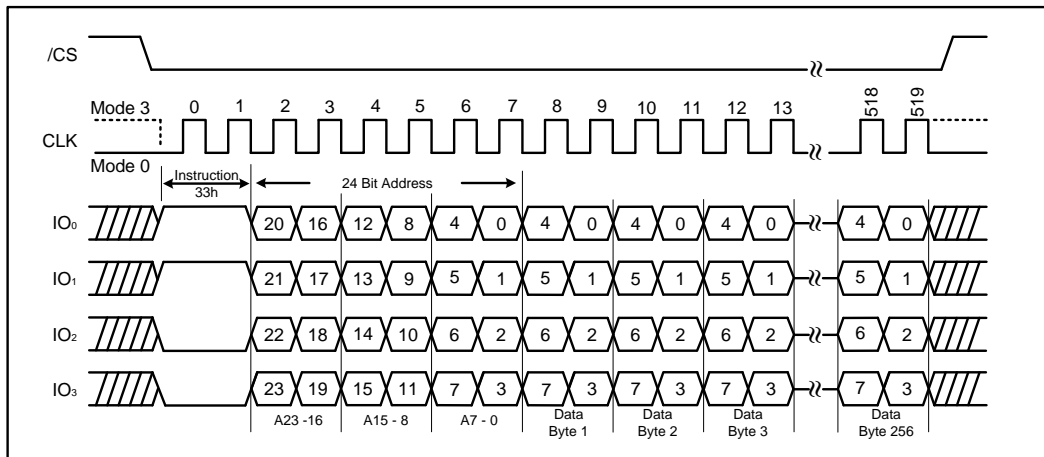


Figure 19b. Quad Page Program Instruction (QPI mode)

10.20 Sector Erase (20h)

The Sector Erase instruction is to erase the data of the selected sector as being "1". The instruction is used for 4K-byte sector. Prior to the Sector Erase Instruction, the Write Enable instruction must be issued. The instruction is initiated by driving the /CS pin low and shifting the instruction code "20h" followed a 24-bit sector address (A23-A0). (Please refer to figure 20). The /CS pin must go high after the eighth bit of the last byte has been latched in, otherwise, the Sector Erase instruction will not be executed. After /CS goes high, the self-timed Sector Erase instruction will commence for a time duration of tSE (See AC Characteristics).

While the Sector Erase cycle is in progress, the Read Status Register instruction may still be accessed for checking the status of the BUSY bit. The BUSY bit is a 1 during the Sector Erase cycle and becomes a 0 when the cycle is finished and the device is ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in the Status Register is cleared to 0. The sector Erase instruction will not be executed if the addressed page is protected by the Protect (CMP, SEC, TB, BP2, BP1 and BP0) bits.

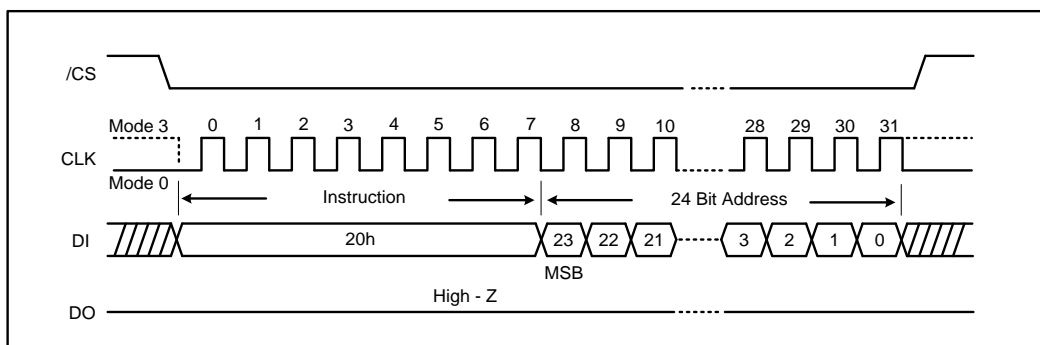


Figure 20a. Sector Erase Instruction (SPI Mode)

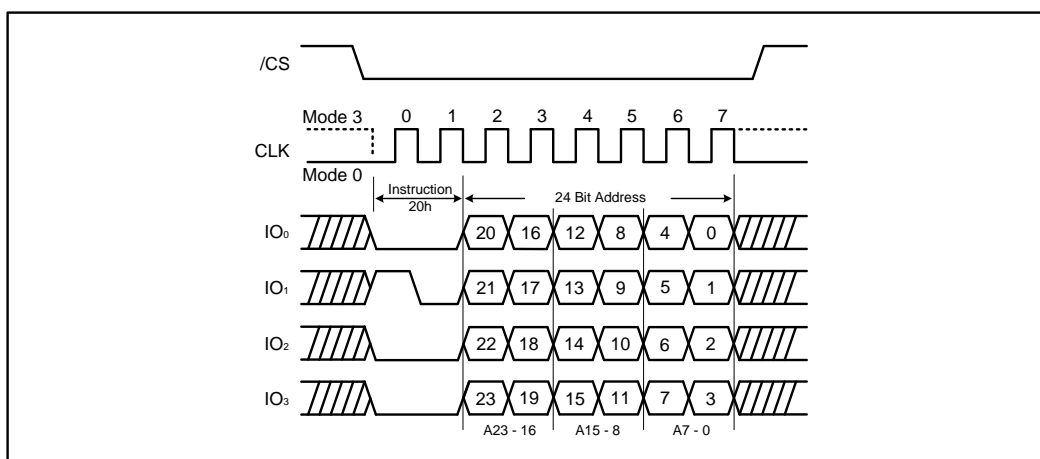


Figure 20b. Sector Erase Instruction (QPI Mode)

10.21 32KB Block Erase (52h)

The Block Erase instruction is to erase the data of the selected block as being “1”. The instruction is used for 32K-byte Block erase operation. Prior to the Block Erase Instruction, a Write Enable instruction must be issued. The instruction is initiated by driving the /CS pin low and shifting the instruction code “52h” followed a 24-bit block address (A23-A0). (Please refer to figure 21). The /CS pin must go high after the eighth bit of the last byte has been latched in, otherwise, the Block Erase instruction will not be executed. After /CS is driven high, the self-timed Block Erase instruction will commence for a time duration of tBE1 (See AC Characteristics).

While the Block Erase cycle is in progress, the Read Status Register instruction may still be read the status of the BUSY bit. The BUSY bit is a 1 during the Block Erase cycle and becomes a 0 when the cycle is finished and the device is ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in the Status Register is cleared to 0. The Block erase instruction will not be executed if the addressed page is protected by the Protect (CMP, SEC, TB, BP2, BP1 and BP0) bits.

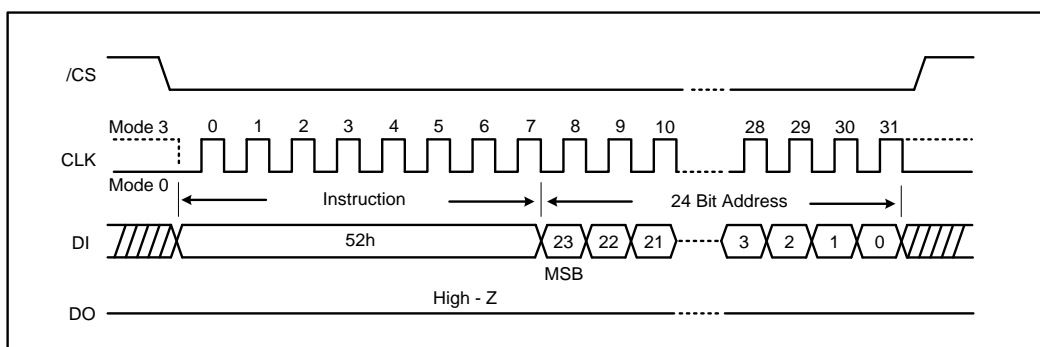


Figure 21a. 32KB Block Erase Instruction (SPI Mode)

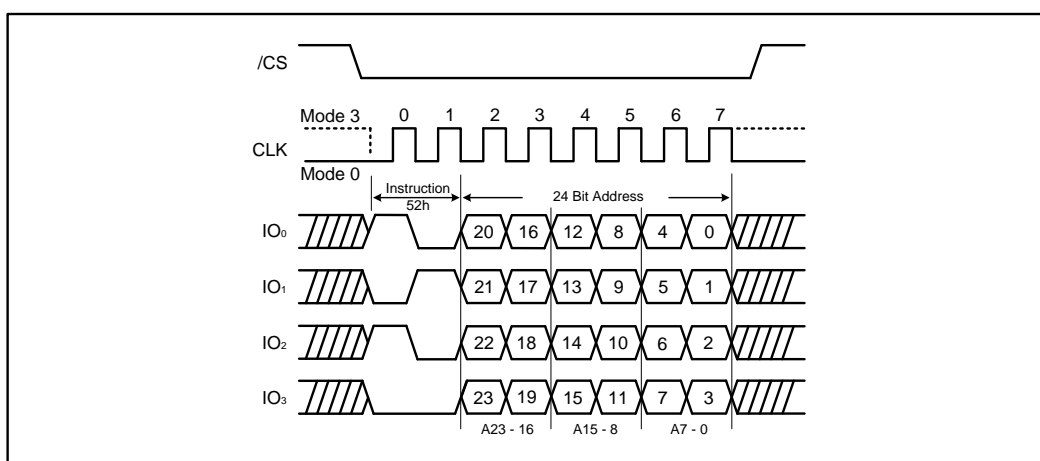


Figure 21b. 32KB Block Erase Instruction (QPI Mode)

10.22 64KB Block Erase (D8h)

The Block Erase instruction is to erase the data of the selected block as being “1”. The instruction is used for 64K-byte Block erase operation. Prior to the Block Erase Instruction, a Write Enable instruction must be issued. The instruction is initiated by driving the /CS pin low and shifting the instruction code “D8h” followed a 24-bit block address (A23-A0). (Please refer to figure 22). The /CS pin must go high after the eighth bit of the last byte has been latched in, otherwise, the Block Erase instruction will not be executed. After /CS is driven high, the self-timed Block Erase instruction will commence for a time duration of tBE2 (See AC Characteristics).

While the Block Erase cycle is in progress, the Read Status Register instruction may still be read the status of the BUSY bit. The BUSY bit is a 1 during the Block Erase cycle and becomes a 0 when the cycle is finished and the device is ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in the Status Register is cleared to 0. The Block erase instruction will not be executed if the addressed page is protected by the Protect (CMP, SEC, TB, BP2, BP1 and BP0) bits.

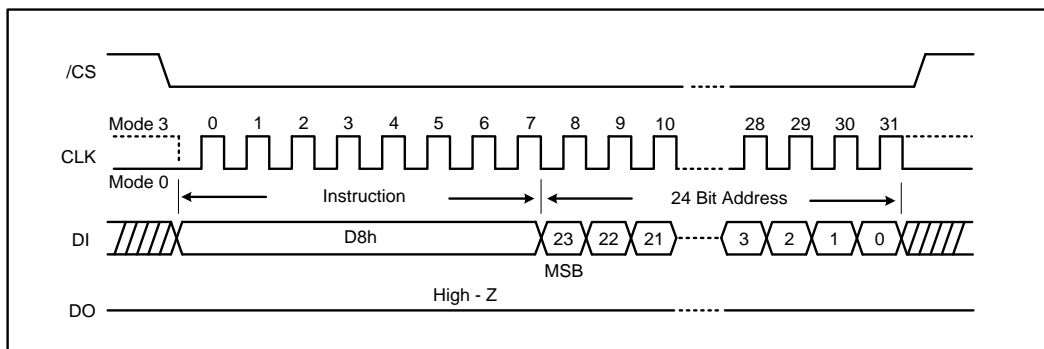


Figure 22a. 64KB Block Erase Instruction (SPI Mode)

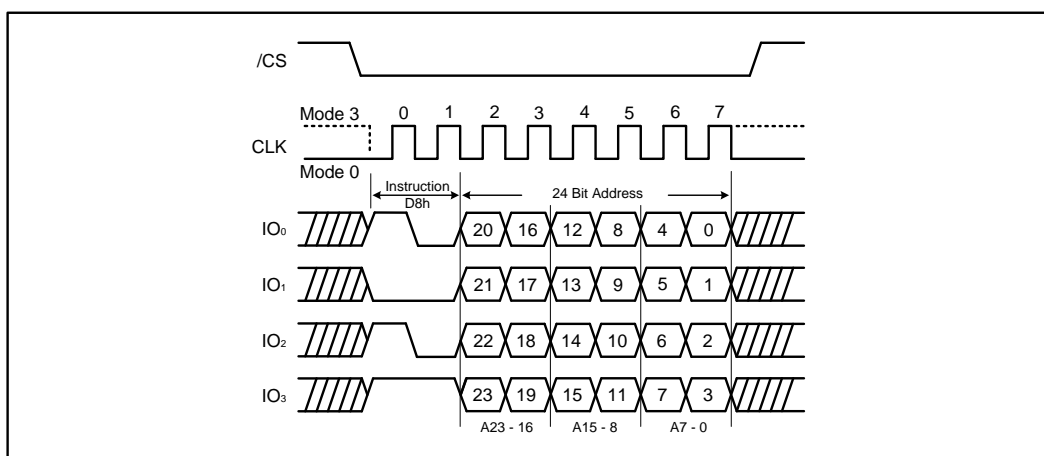


Figure 22b. 64KB Block Erase Instruction (QPI Mode)

10.23 Chip Erase (C7h / 60h)

The Chip Erase instruction clears all bits in the device to be FFh (all 1s). Prior to the Chip Erase Instruction, a Write Enable instruction must be issued. The instruction is initiated by driving the /CS pin low and shifting the instruction code "C7h" or "60h". (Please refer to figure 23). The /CS pin must go high after the eighth bit of the last byte has been latched in, otherwise, the Chip Erase instruction will not be executed. After /CS is driven high, the self-timed Chip Erase instruction will commence for a duration of tCE (See AC Characteristics).

While the Chip Erase cycle is in progress, the Read Status Register instruction may still be accessed to check the status of the BUSY bit. The BUSY bit is a 1 during the Chip Erase cycle and becomes a 0 when the cycle is finished and the device is ready to accept other instructions again. When the BUSY bit is asserted, the Write Enable Latch (WEL) bit in the Status Register is cleared to 0. The Chip erase instruction will not be executed if any page is protected by the Protect (CMP, SEC, TB, BP2, BP1 and BP0) bits.

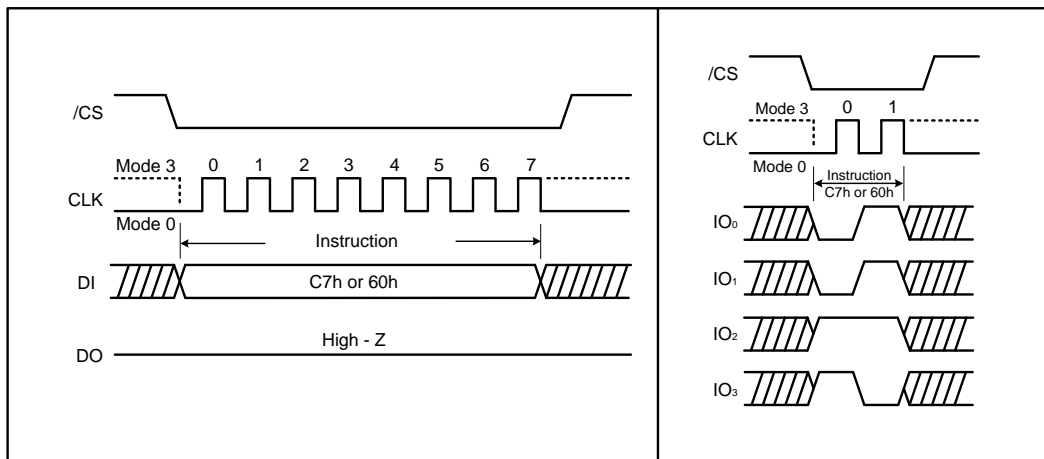


Figure 23. Chip Erase Instruction for SPI Mode (left) and QPI Mode (right)

10.24 Erase / Program Suspend (75h)

The Erase/Program Suspend instruction allows the system to interrupt a Sector Erase, Block Erase operation or a Page Program, Quad Page Program operation.

Erase Suspend is valid only during the Sector or Block erase operation. The Write Status Register-1 (01h), Write Status Register-2 (31h) instruction and Erase instructions (20h, 52h, D8h, C7h, 60h) are not allowed during Erase Suspend. During the Chip Erase operation, the Erase Suspend instruction is ignored.

Program Suspend is valid only during the Page Program, Quad Page Program operation. The Write Status Register-1 (01h), Write Status Register-2 (31h) instruction, Program instructions (02h and 33h) and Erase Instructions (20h, 52h, D8h, C7h, 60h) are not allowed during Program Suspend.

The Erase/Program Suspend instruction “75h” will be accepted by the device only if the SUS bit in the Status Register equals to 0 and the BUSY bit equals to 1 while a Sector or Block Erase or a Page Program operation is on-going. If the SUS bit equals to 1 or the BUSY bit equals to 0, the Suspend instruction will be ignored by the device. A maximum of time of “tSUS” (See AC Characteristics) is required to suspend the erase or program operation. After Erase/Program Suspend, the SUS bit in the Status Register will be set from 0 to 1 immediately and The BUSY bit in the Status Register will be cleared from 1 to 0 within “tSUS”. For a previously resumed Erase/Program operation, it is also required that the Suspend instruction “75h” is not issued earlier than a minimum of time of “tSUS” following the preceding Resume instruction “7Ah”.

Unexpected power off during the Erase/Program suspend state will reset the device and release the suspend state. SUS bit in the Status Register will also reset to 0. The data within the page, sector or block that was being suspended may become corrupted. It is recommended for the user to implement system design techniques against the accidental power interruption and preserve data integrity during erase/program suspend state. (Please refer to figure 24).

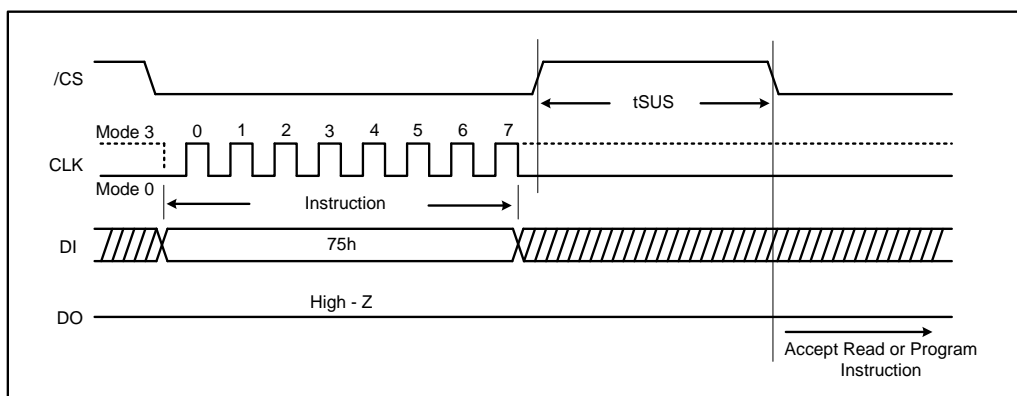


Figure 24a. Erase Suspend instruction (SPI Mode)

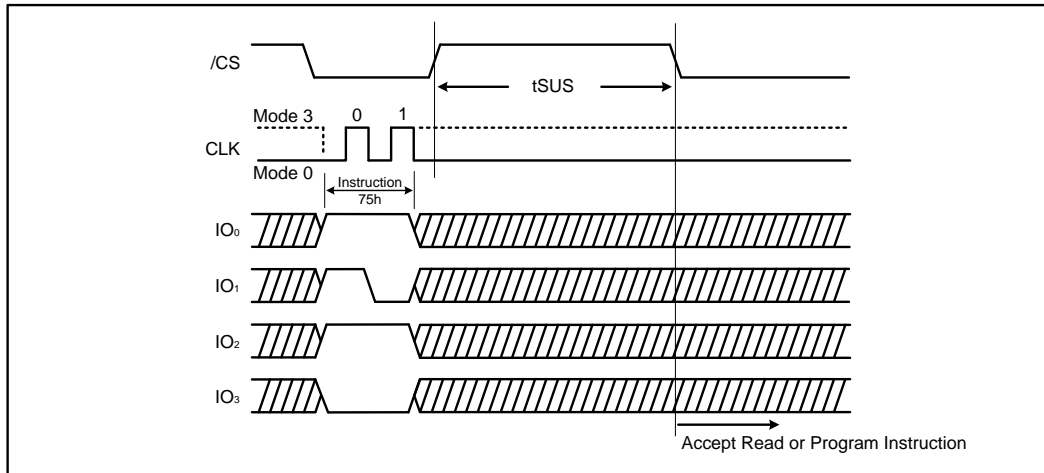


Figure 24b. Erase Suspend instruction (QPI Mode)

10.25 Erase / Program Resume (7Ah)

The Erase/Program Resume instruction “7Ah” is to re-work the Sector or Block Erase operation or the Page Program operation upon an Erase/Program Suspend. The Resume instruction “7Ah” will be accepted by the device only if the SUS bit in the Status Register equals to 1 and the BUSY bit equals to 0. After issued, the SUS bit will be cleared from 1 to 0 immediately, the BUSY bit will be set from 0 to 1 within 200ns and the Sector or Block will complete the erase operation or the page will complete the program operation. If the SUS bit equals to 0 or the BUSY bit equals to 1, the Resume instruction “7Ah” will be ignored by the device.

Resume instruction cannot be accepted if the previous Erase/Program Suspend operation was interrupted by unexpected power off. It is also required that a subsequent Erase/Program Suspend instruction not to be issued within a minimum of time of “tSUS” following a previous Resume instruction. (Please refer to figure 25).

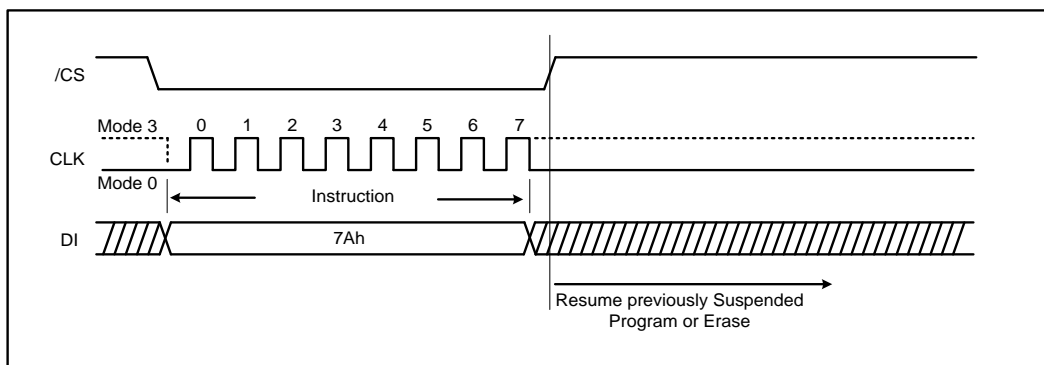


Figure 25a. Erase / Program Resume instruction (SPI Mode)

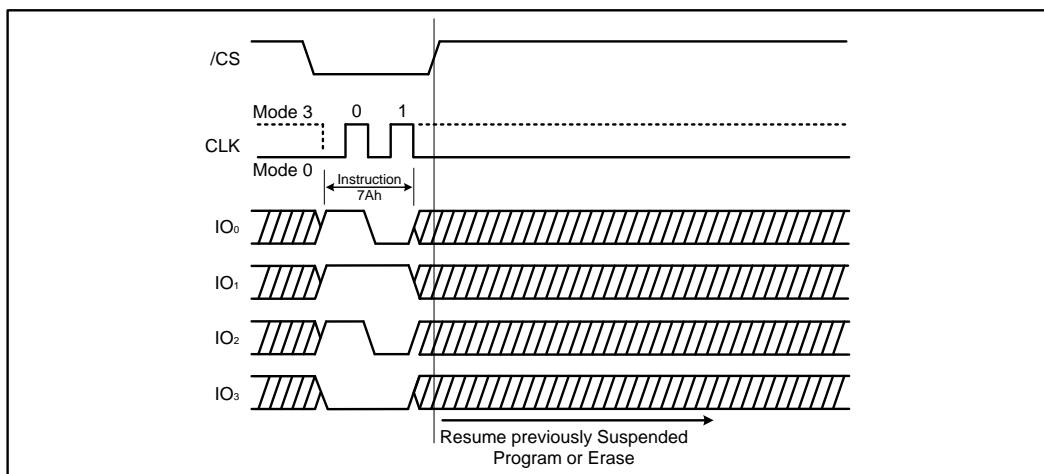


Figure 25b. Erase / Program Resume instruction (QPI Mode)

10.26 Deep Power-down (B9h)

Executing the Deep Power-down instruction is the best way to put the device in the lowest power consumption. The Deep Power-down instruction reduces the standby current (from ICC1 to ICC2, as specified in AC characteristics). The instruction is entered by driving the /CS pin low with following the instruction code "B9h". (Please refer to figure 26).

The /CS pin must go high exactly at the byte boundary (the latest eighth bit of instruction code been latched-in); otherwise, the Deep Power-down instruction is not executed. After /CS goes high, it requires a delay of tDP and the Deep Power-down mode is entered. While in the Release Deep Power-down / Device ID instruction, which restores the device to normal operation, will be recognized. All other instructions are ignored including the Read Status Register instruction, which is always available during normal operation. Deep Power-down Mode automatically stops at Power-Down, and the device always Power-up in the Standby Mode.

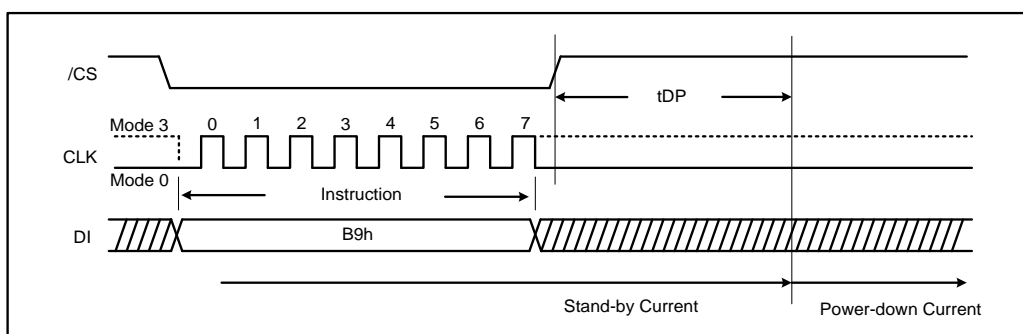


Figure 26a. Deep Power-down Instruction (SPI Mode)

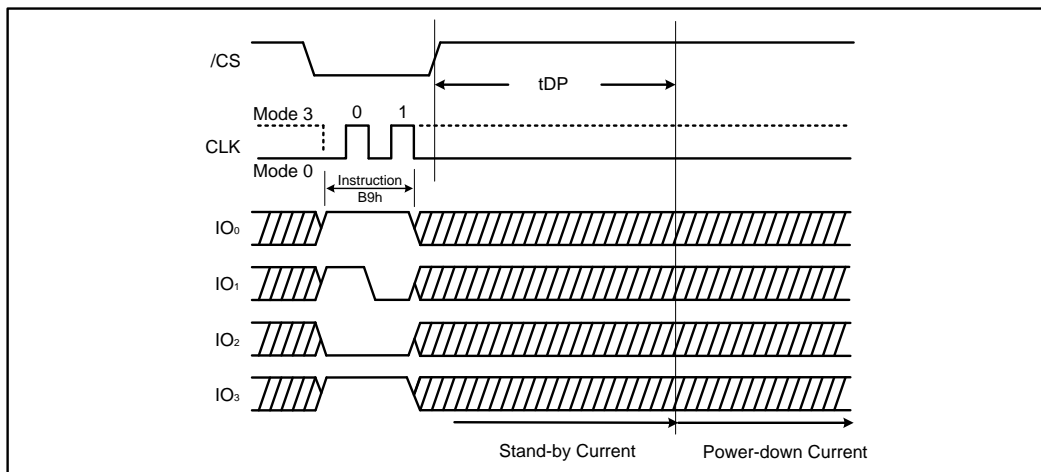


Figure 26b. Deep Power-down Instruction (QPI Mode)

10.27 Release Deep Power-down / Device ID (ABh)

The Release Deep Power-down / Device ID instruction is a multi-purpose instruction. It can be used to release the device from the Deep Power-down state or obtain the device identification (ID).

The instruction is issued by driving the /CS pin low, sending the instruction code “ABh” and driving /CS high as shown in figure 27a & 27b. Release from Deep Power-down require the time duration of tRES1 (See AC Characteristics) for re-work a normal operation and accepting other instructions. The /CS pin must keep high during the tRES1 time duration.

The Device ID can be read during SPI mode only. In other words, Device ID feature is not available in QPI mode for Release Deep power-down/Device ID instruction.

To obtain the Device ID in SPI mode, instruction is initiated by driving the /CS pin low and sending the instruction code “ABh” with following 3-dummy bytes. The Device ID bits are then shifted on the falling edge of CLK with most significant bit (MSB) first as shown in figure 27c. After /CS is driven high it must keep high for a time duration of tRES2 (See AC Characteristics). The Device ID can be read continuously. The instruction is completed by driving /CS high.

If the Release from Deep Power-down /Device ID instruction is issued while an Erase, Program or Write cycle is in process (when BUSY equals 1) the instruction is ignored and will not have any effects on the current cycle.

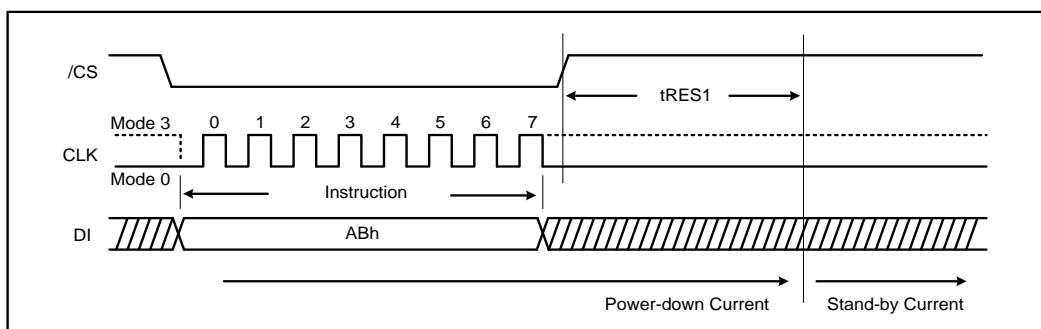


Figure 27a. Release power-down Instruction (SPI Mode)

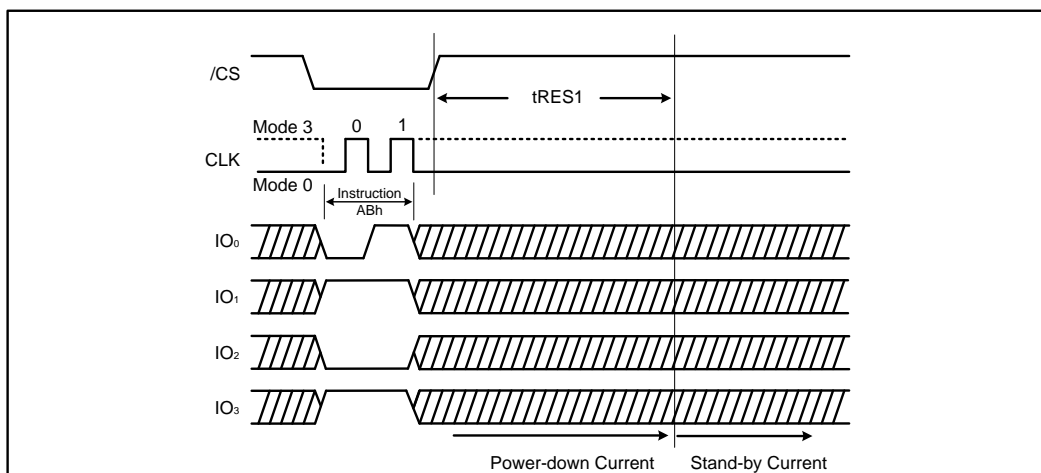


Figure 27b. Release power-down Instruction (QPI Mode)

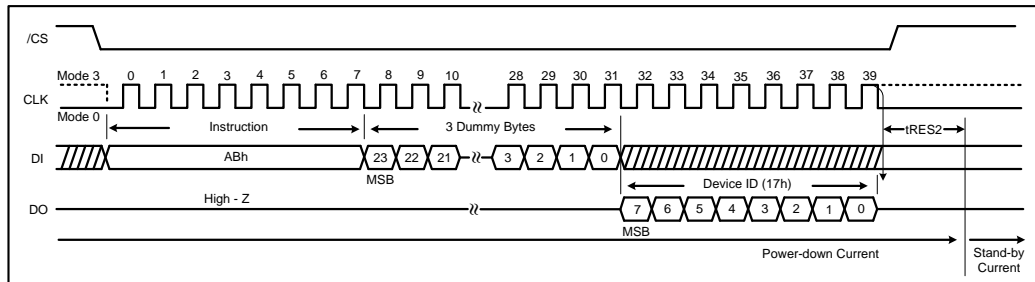


Figure 27c. Release power-down / Device ID Instruction (SPI Mode)

The Read Manufacturer/ Device ID instruction provides both the JEDEC assigned manufacturer ID and the specific device ID.

The diagram illustrates the timing for a Mode 0 read cycle. It is divided into two main sections. The first section shows the initial read cycle where the instruction is 90h and the 24-bit address is 000000h or 000001h. The second section shows the read cycle for the Manufacturer ID (52h) and Device ID (17h).

Signal Definitions:

- /CS:** Chip Select, active low. It transitions from high to low at the start of the first cycle and returns to high at the end of the second cycle.
- CLK:** Clock signal, shown as a series of pulses.
- DI:** Data Input. It is used to load the instruction and address.
- DO:** Data Output. It provides the data from the device.

First Section (Instruction and Address):

- Mode 3:** Indicated by a dashed line for the first 3 clock cycles.
- Mode 0:** Indicated by a solid line for the subsequent clock cycles.
- Instruction:** 90h, loaded over 8 clock cycles (bits 23 to 16).
- 24 Bit Address:** 000000h or 000001h, loaded over 8 clock cycles (bits 23 to 0).
- MSB:** Most Significant Bit, indicated for the instruction and address.
- High - Z:** The output is in a high-impedance state during this phase.

Second Section (Manufacturer ID and Device ID):

- Manufacturer ID (52h):** Loaded over 13 clock cycles (bits 31 to 19).
- Device ID (17h):** Loaded over 4 clock cycles (bits 16 to 12).
- MSB:** Most Significant Bit, indicated for the Manufacturer ID and Device ID.

Rev.1.0 June 2022

10.29 Read Manufacturer / Device ID Dual I/O (92h)

The Read Manufacturer/ Device ID Dual I/O instruction provides both the JEDEC assigned manufacturer ID and the specific device ID.

The Read Manufacturer/ Device ID instruction is very similar to the Fast Read Dual I/O instruction. The instruction is initiated by driving the /CS pin low and shifting the instruction code "92h" followed by a 24-bit address (A23-A0) of 000000h. After which, the Manufacturer ID for Alliance Memory (52h) and the Device ID (17h) are shifted out on the falling edge of CLK with most significant bit (MSB) first as shown in figure 29. If the 24-bit address is initially set to 000001h the Device ID will be read first and then followed by the Manufacturer ID. The Manufacturer and Device ID can be read continuously, alternating from one to the other. The instruction is completed by driving /CS high.

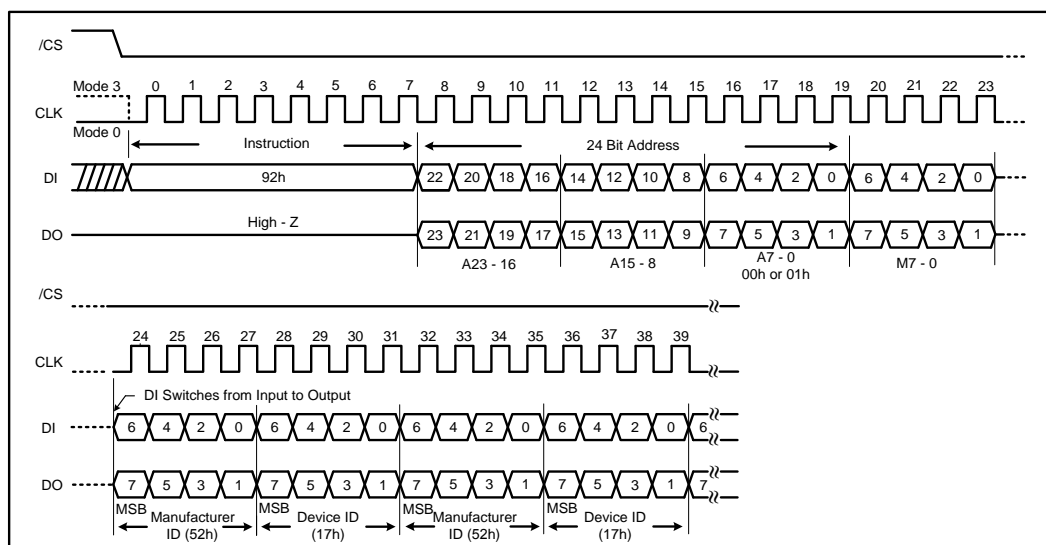


Figure 29. Read Dual Manufacturer/ Device ID Dual I/O instruction (SPI Mode)

10.30 Read Manufacturer / Device ID Quad I/O (94h)

The Read Manufacturer/ Device ID Quad I/O instruction provides both the JEDEC assigned manufacturer ID and the specific device ID.

The Read Manufacturer/ Device ID instruction is very similar to the Fast Read Quad I/O instruction. The instruction is initiated by driving the /CS pin low and shifting the instruction code "94h" followed by a 24-bit address (A23-A0) of 000000h. After which, the Manufacturer ID for Alliance Memory (52h) and the Device ID (17h) are shifted out on the falling edge of CLK with most significant bit (MSB) first as shown in figure 30. If the 24-bit address is initially set to 000001h the Device ID will be read first and then followed by the Manufacturer ID. The Manufacturer and Device ID can be read continuously, alternating from one to the other. The instruction is completed by driving /CS high.

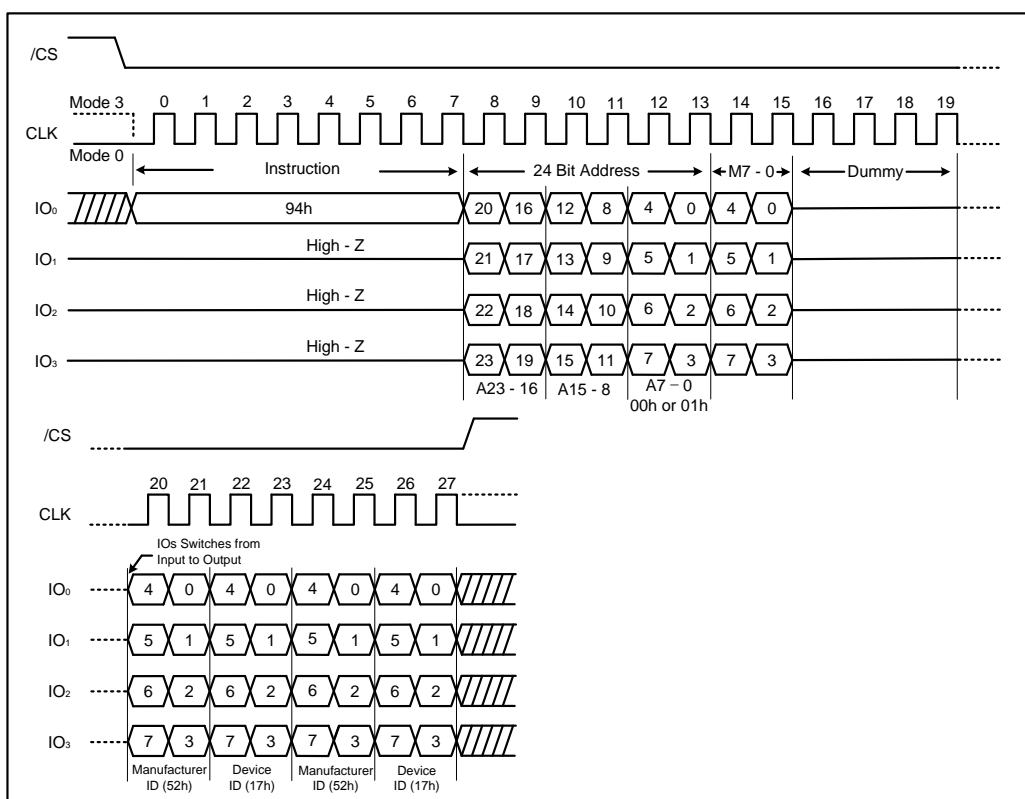


Figure 30. Read Quad Manufacturer/ Device ID Quad I/O instruction (SPI Mode)

10.31 JEDEC ID (9Fh)

For compatibility reasons, the AS25F1128MQ provides several instructions to electronically determine the identity of the device. The Read JEDEC ID instruction is congruous with the JEDEC standard for SPI compatible serial flash memories that was adopted in 2003. The instruction is entered by driving the /CS pin low with following the instruction code "9Fh". JEDEC assigned Manufacturer ID byte for Alliance Memory (52h) and two Device ID bytes, Memory Type (ID15-ID8) and Capacity (ID7-ID0) are then shifted out on the falling edge of CLK with most significant bit (MSB) first shown in figure 31. For memory type and capacity values refer to Manufacturer and Device Identification table. The JEDEC ID can be read continuously. The instruction is terminated by driving /CS high.

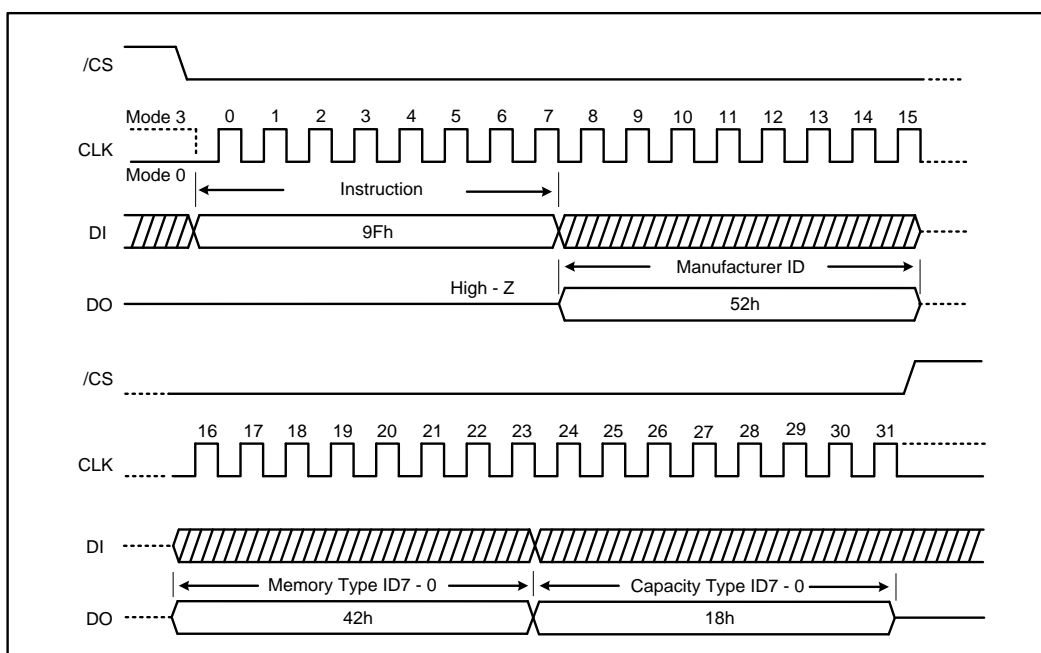


Figure 31a. Read JEDEC ID instruction (SPI Mode)

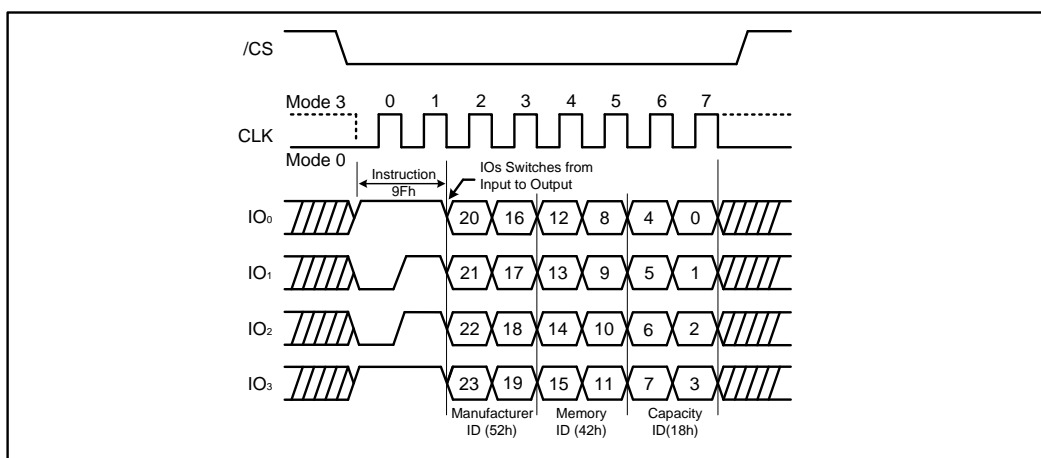


Figure 31b. Read JEDEC ID instruction (QPI Mode)

10.32 Enable QPI (38h)

The AS25F1128MQ support both Standard/Dual/Quad Serial Peripheral interface (SPI) and Quad Peripheral Interface (QPI). However, SPI mode and QPI mode cannot be used at the same time. Enable QPI instruction is the only way to switch the device from SPI mode to QPI mode.

In order to switch the device to QPI mode, the Quad Enable (QE) bit in Status Register 2 must be set to 1 first, and an Enable QPI instruction must be issued. If the Quad Enable (QE) bit is 0, the Enable QPI instruction will be ignored and the device will remain in SPI mode.

After power-up, the default state of the device is SPI mode. See the instruction Set Table 1-3 for all the commands supported in SPI mode and the instruction Set Table 4 for all the instructions supported in QPI mode.

When the device is switched from SPI mode to QPI mode, the existing Write Enable and Program/Erase Suspend status, and the Wrap Length setting will remain unchanged.

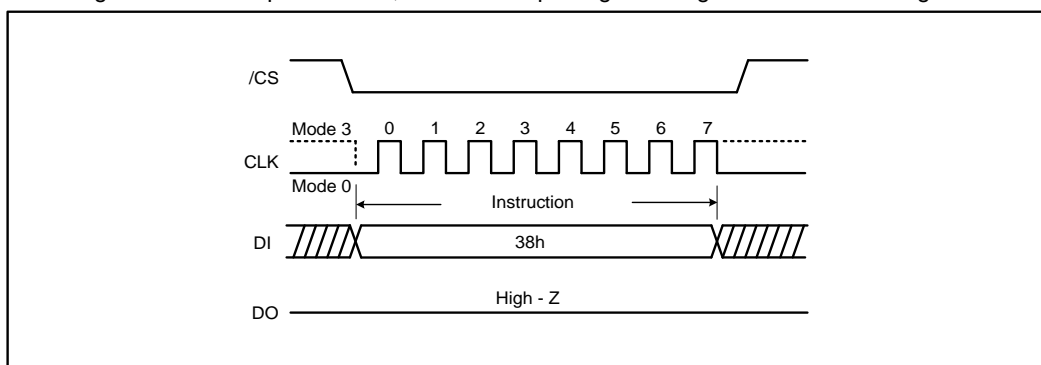


Figure 32. Enable QPI instruction (SPI Mode only)

10.33 Disable QPI (FFh)

By issuing Disable QPI (FFh) instruction, the device is reset SPI mode. When the device is switched from QPI mode to SPI mode, the existing Write Enable Latch (WEL) and Program/Erase Suspend status, and the Wrap Length setting will remain unchanged.

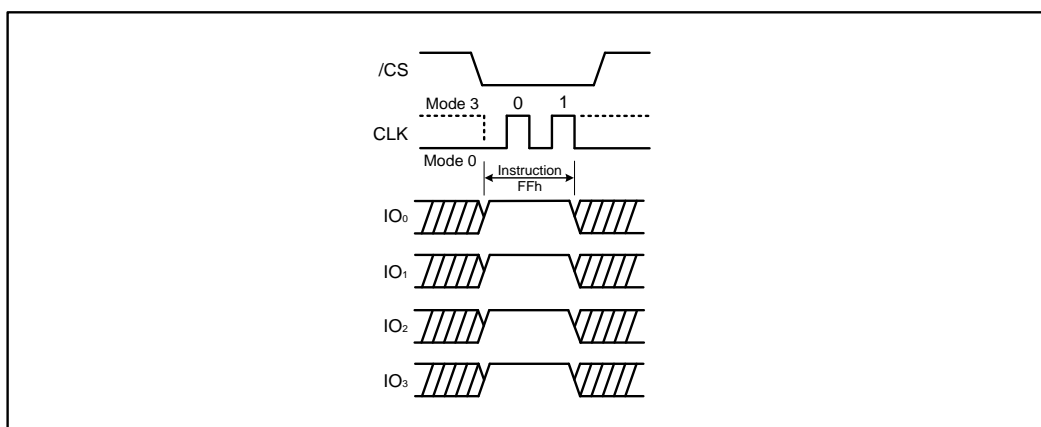


Figure 33. Disable QPI instruction for QPI mode

10.34 Word Read Quad I/O (E7h)

The Quad I/O dramatically reduces instruction overhead allowing faster random access for code execution (XIP) directly from the Quad SPI. The Quad Enable bit (QE) of Status Register-2 must be set to enable the Word Read Quad I/O instruction. The lowest Address bit (A0) must equal 0 and only two dummy clocks are required prior to the data output.

Continuous Read Mode

The Word Read Quad I/O instruction can further reduce instruction overhead through setting the “Continuous Read Mode” bits (M7-0) after the input Address bits (A23-0), as shown in Figure 34a. The upper nibble of the (M7-4) controls the length of the next Word Read Quad I/O instruction through the inclusion or exclusion of the first byte instruction code. The lower nibble bits of the (M[3:0]) are don't care (“X”). However, the IO pins should be high-impedance prior to the falling edge of the first data out clock.

If the “Continuous Read Mode” bits M[7-4]= Ah, then the next Fast Read Quad I/O instruction (after /CS is raised and then lowered) does not require the E7h instruction code, as shown in Figure 34b. This reduces the instruction sequence by eight clocks and allows the Read address to be immediately entered after /CS is asserted low. If the “Continuous Read Mode” bits M[7:4] do not equal to Ah(1,0,1,0) the next instruction (after /CS is raised and then lowered) requires the first byte instruction code, thus returning to normal operation.

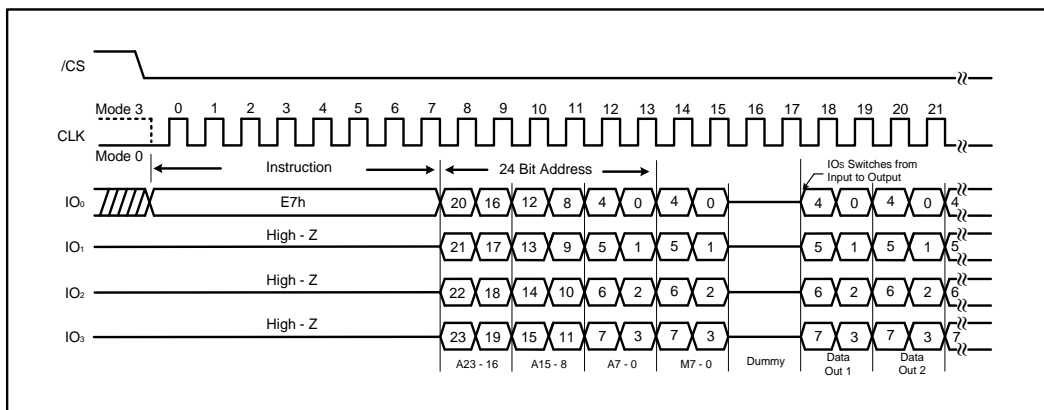


Figure 34a. Word Read Quad I/O instruction (Initial instruction or previous set M7-0 ≠ Ah, SPI Mode)

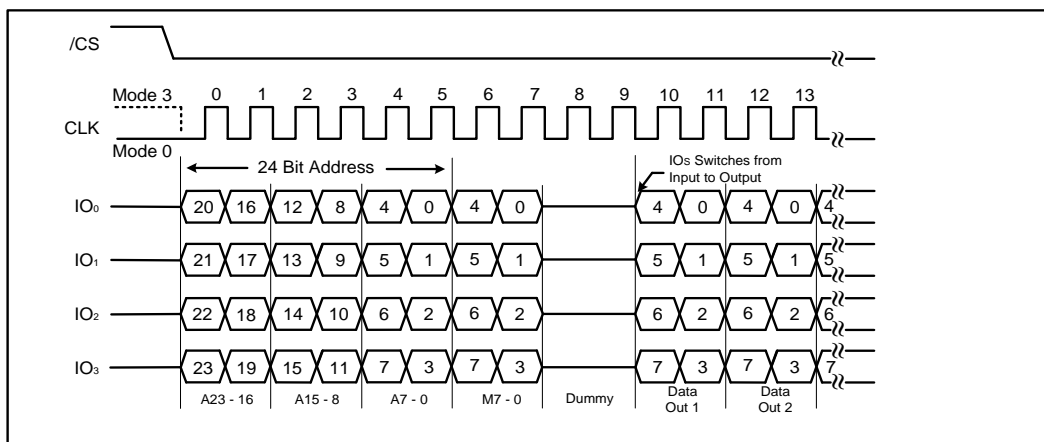


Figure 34b. Word Read Quad I/O instruction (Previous instruction set M7-0 = Ah, SPI Mode)

Wrap Around in SPI mode

The Word Read Quad I/O instruction can also be used to access a specific portion within a page by issuing a “Set Burst with Wrap” (77h) instruction prior to E7h. The “Set Burst with Wrap” (77h) instruction can either enable or disable the “Wrap Around” feature for the following E7h commands. When “Wrap Around” is enabled, the output data starts at the initial address specified in the instruction, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around to the beginning boundary automatically until /CS is pulled high to terminate the instruction.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing read instructions.

The “Set Burst with Wrap” instruction allows three “Wrap Bits”, W6-4 to be set. The W4 bit is used to enable or disable the “Wrap Around” operation while W6-5 is used to specify the length of the wrap around section within a page. See 10.35 for detail descriptions.

10.35 Set Burst with Wrap (77h)

The Set Burst with Wrap (77h) instruction is used in conjunction with “Fast Read Quad I/O” and “Word Read Quad I/O” instructions to access a fixed length of 8/16/32/64-byte section within a 256-byte page. Certain applications can benefit from this feature and improve the overall system code execution performance. Before the device will accept the Set Burst with Wrap instruction, a Quad enable of Status Register-2 must be executed (Status Register bit QE must equal 1).

The Set Burst with Wrap instruction is initiated by driving the /CS pin low and then shifting the instruction code “77h” followed by 24 dummy bits and 8 “Wrap Bits”, W7-0. The instruction sequence is shown in Set Burst with Wrap Instruction Sequence. Wrap bit W7 and W3-0 are not used.

W6, W5	W4 = 0		W4 = 1(Default)	
	Wrap Around	Wrap Length	Wrap Around	Wrap Length
0 0	Yes	8-byte	No	N/A
0 1	Yes	16-byte	No	N/A
1 0	Yes	32-byte	No	N/A
1 1	Yes	64-byte	No	N/A

Once W6-4 is set by a Set Burst with Wrap instruction, all the following “Fast Read Quad I/O” and Word Read Quad I/O instructions will use the W6-4 setting to access the 8/16/32/64-byte section within any page. To exit the “Wrap Around” function and return to normal read operation, another Set Burst with Wrap instruction should be issued to set W4 = 1. The default value of W4 upon power on is 1. In the case of a system Reset while W4 = 0, it is recommended that the controller issues a Set Burst with Wrap instruction or Reset (99h) instruction to reset W4 = 1 prior to any normal Read instructions since AS25F1128MQ does not have a hardware Reset Pin.

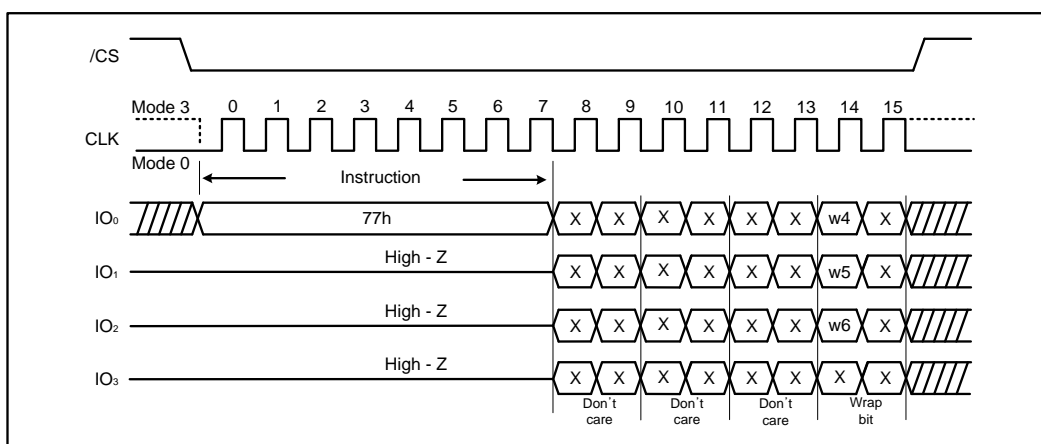


Figure 35. Set Burst with Wrap Instruction Sequence

10.36 Burst Read with Wrap (0Ch)

The “Burst Read with Wrap (0Ch)” instruction provides an alternative way to perform the read operation with “Wrap Around” in QPI mode. The instruction is similar to the “Fast Read (0Bh)” instruction in QPI mode, except the addressing of the read operation will “Wrap Around” to the beginning boundary of the “Wrap Length” once the ending boundary is reached.

The “Wrap Length” and the number of dummy of clocks can be configured by the “Set Read Parameters (C0h)” instruction.

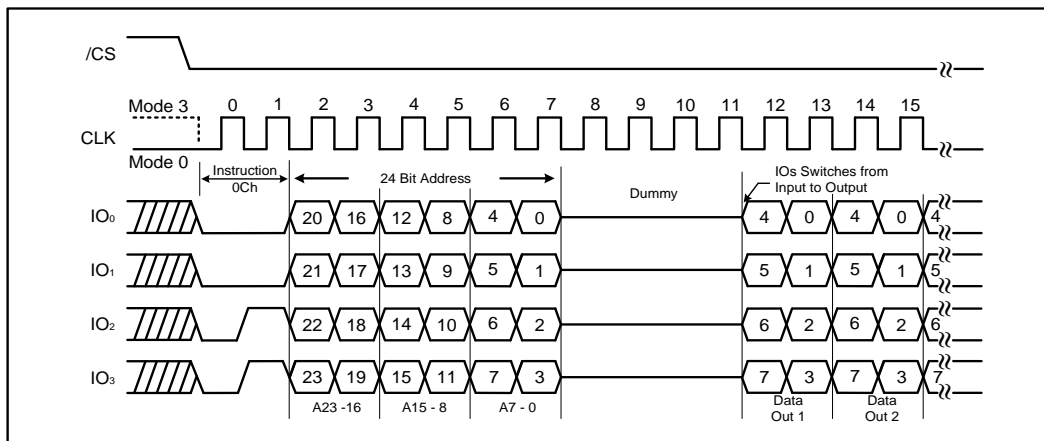


Figure 36a. Burst Read with Wrap instruction (QPI Mode, 80MHz)

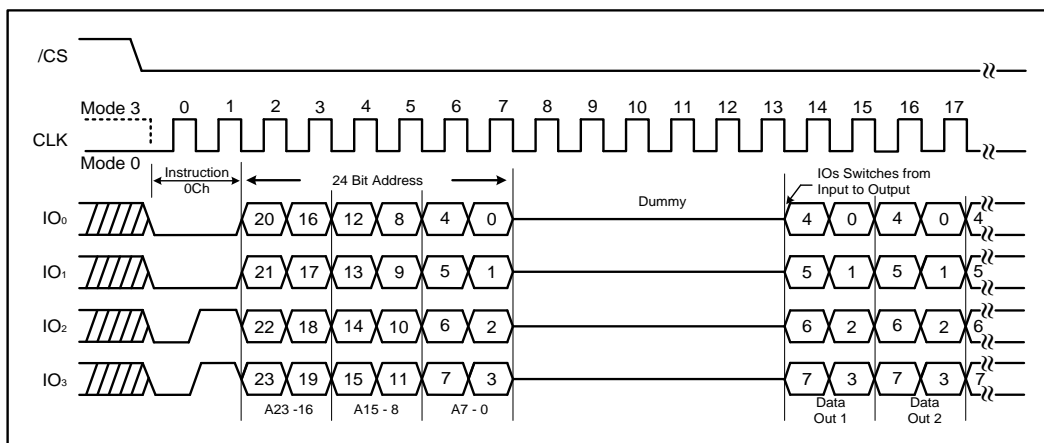


Figure 36b. Burst Read with Wrap instruction (QPI Mode, 108MHz)

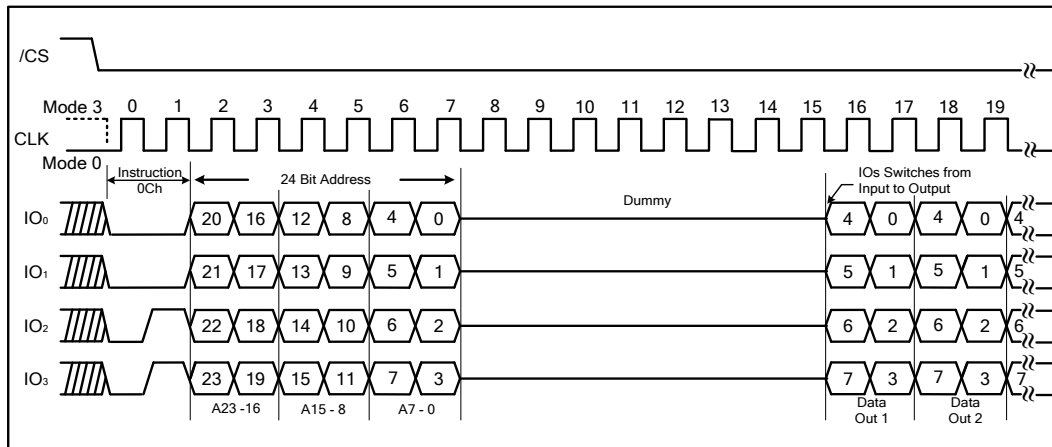


Figure 36c. Burst Read with Wrap instruction (QPI Mode, 133MHz)

10.37 Set Read Parameters (C0h)

In QPI mode, to accommodate a wide range of applications with different needs for either maximum read frequency or minimum data access latency, “Set Read Parameters (C0h)” instruction can be used to configure the number of dummy clocks for “Fast Read (0Bh)”, “Fast Read Quad I/O (EBh)” & “Burst Read with Wrap (0Ch)” instructions, and to configure the number of bytes of “Wrap Length” for the “Burst Read with Wrap (0Ch)” instruction.

In Standard SPI mode, the “Set Read Parameters (C0h)” instruction is not accepted. The dummy clocks for various Fast Read instructions in Standard/Dual/Quad SPI mode are fixed, please refer to the instruction. Table 10.2 - 10.5 for details. The “Wrap Length” is set by W6-5 bit in the “Set Burst with Wrap (77h)” instruction. This setting will remain unchanged when the device is switched from Standard SPI mode to QPI mode.

The default “Wrap Length” after a power up or a Reset instruction is 8 bytes, the default number of dummy clocks is 4.

P5, P4	Dummy Clocks	Maximum Read Freq.
0 0	4	80MHz
0 1	4	80MHz
1 0	6	108MHz
1 1	8	133MHz

P1, P0	Wrap Length
0 0	8-byte
0 1	16-byte
1 0	32-byte
1 1	64-byte

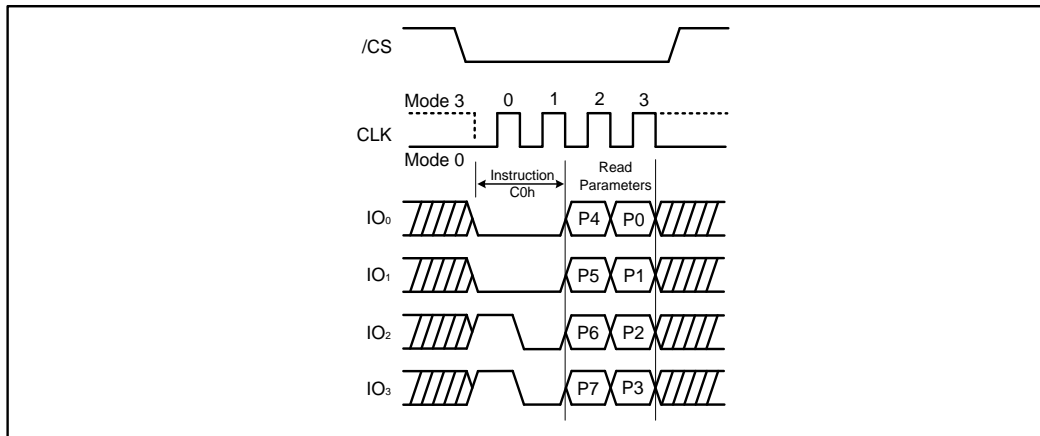


Figure 37. Set Read Parameters instruction (QPI Mode)

10.38 Enable Reset (66h) and Reset (99h)

Because of the small package and the limitation on the number of pins, the AS25F1128MQ provide a software Reset instruction instead of a dedicated RESET pin.

Once the Reset instruction is accepted, any on-going internal operations will be terminated and the device will return to its default power-on state and lose all the current volatile settings, such as Volatile Status Register bits, Write Enable Latch (WEL) status, Program/Erase Suspend status, Continuous Read Mode bit setting, Read parameter setting and Wrap bit setting.

“Enable Reset (66h)” and “Reset (99h)” instructions can be issued in either SPI mode or QPI mode. To avoid accidental reset, both instructions must be issued in sequence. Any other instructions other than “Reset (99h)” after the “Enable (66h)” instruction will disable the “Reset Enable” state. A new sequence of “Enable Reset (66h)” and “Reset (99h)” is needed to reset the device. Once the Reset instruction is accepted by the device will take approximately $t_{RST} = 30\mu s$ to reset. During this period, no instruction will be accepted.

Data corruption may happen if there is an on-going or suspended internal Erase or Program operation when Reset instruction sequence is accepted by device. It is recommended to check the BUSY bit and the SUS bit in Status Register before issuing the Reset instruction sequence.

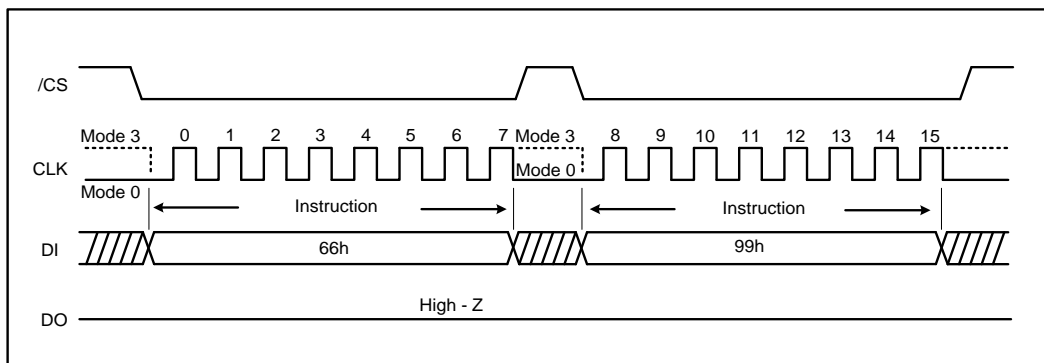


Figure 38a. Enable Reset and Reset Instruction (SPI Mode)

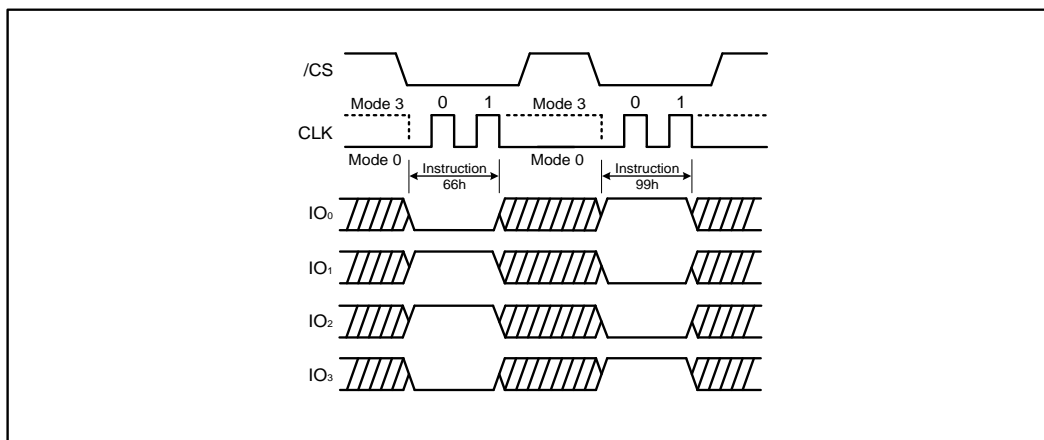


Figure 38b. Enable Reset and Reset Instruction (QPI Mode)

10.39 Read Serial Flash Discovery Parameter (5Ah)

The Read Serial Flash Discovery Parameter (SFDP) instruction allows reading the Serial Flash Discovery Parameter area (SFDP). This SFDP area is composed of 2048 read-only bytes containing operating characteristics and vendor specific information. The SFDP area is factory programmed. If the SFDP area is blank, the device is shipped with all the SFDP bytes at FFh. If only a portion of the SFDP area is written to, the portion not used is shipped with bytes in erased state (FFh). The instruction sequence for the read SFDP has the same structure as that of a Fast Read instruction. First, the device is selected by driving Chip Select (/CS) Low. Next, the 8-bit instruction code (5Ah) and the 24-bit address are shifted in, followed by 8 dummy clock cycles. The bytes of SFDP content are shifted out on the Serial Data Output (DO) starting from the specified address. Each bit is shifted out during the falling edge of Serial Clock (CLK). The instruction sequence is shown here. The Read SFDP instruction is terminated by driving Chip Select (/CS) High at any time during data output.

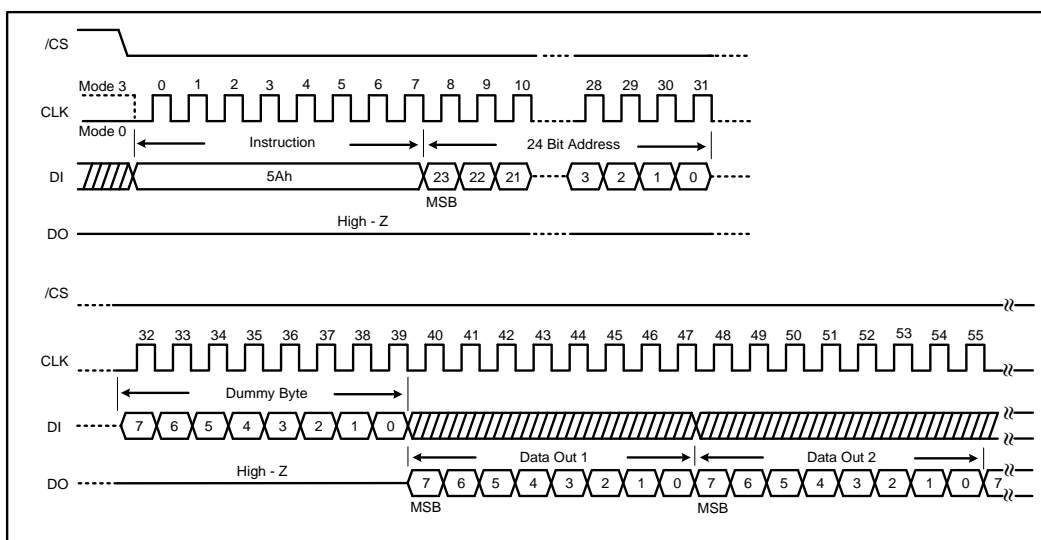


Figure 39. Read SFDP Register Instruction

Read Serial Flash Discovery Parameter (SFDP)

BYTE ADDRESS	DATA	DESCRIPTION	COMMENT
00h	53h	SFDP Signature	SFDP Signature =50444653h
01h	46h	SFDP Signature	
02h	44h	SFDP Signature	
03h	50h	SFDP Signature	
04h	01h	SFDP Minor Revisions	SFDP revision 1.1
05h	01h	SFDP Major Revisions	
06h	00h	Number of Parameter Header(NPH)	1 Parameter Header
07h	FFh	Reserved	
08h	52h	PID(0) ⁽³⁾ : Manufacture JEDEC ID	52h = Alliance Memory
09h	00h	PID(0) : Serial Flash Basics Minor Revisions	Serial Flash Basics Revision 1.0
0Ah	01h	PID(0) : Serial Flash Basics Major Revisions	
0Bh	04h	PID(0) : Serial Flash Basics Length	4 Dwords ⁽²⁾
0Ch	80h	PID(0) : Address of Parameter ID(0) Table (A7-A0)	PID(0) Table Address = 000080h
0Dh	00h	PID(0) : Address of Parameter ID(0) Table (A15-A8)	
0Eh	00h	PID(0) : Address of Parameter ID(0) Table (A23-A16)	
0Fh	FFh	Reserved	
... ⁽¹⁾	FFh	Reserved	
80h	E5h	Bit[7:5] = 111 Reserved	
		Bit[4:3] = 00 Non-volatile Status Register	
		Bit[2] = 1 Page Programmable	
		Bit[1:0] = 01 Support 4KB Erase	

Read Serial Flash Discovery Parameter (SFDP) (cont'd)

BYTE ADDRESS	DATA	DESCRIPTION	COMMENT
81h	20h	Opcode for 4K-Byte Erase	
82h	F1h	Bit[7] = 1 Reserved	
		Bit[6] = 1 Supports Single Input Quad Output	
		Bit[5] = 1 Supports Quad Input Quad Output	
		Bit[4] = 1 Supports Dual Input Dual Output	
		Bit[3] = 0 Dual Transfer Rate not Supported	
		Bit[2:1] = 00 3-Byte/24-Bit Addressing	
		Bit[0] = 1 Supports Single Input Dual Output	
83h	FFh	Reserved	
84h	FFh	Flash Size in Bits	128 Mega Bits = 07FFFFFFh
85h	FFh	Flash Size in Bits	
86h	FFh	Flash Size in Bits	
87h	07h	Flash Size in Bits	
88h	44h	Bit[7:5] = 010 8 Mode Bits are needed	Fast Read Quad I/O Setting
		Bit[4:0] = 00100 16 Dummy Bits are needed	
89h	EBh	Opcode for Quad Input Quad Output Fast Read	
8Ah	08h	Bit[7:5] = 000 No Mode Bits are needed	Fast Read Quad Output Setting
		Bit[4:0] = 01000 8 Dummy Bits are needed	
8Bh	6Bh	Opcode for Single Input Quad Output Fast Read	
8Ch	08h	Bit[7:5] = 000 No Mode Bits are needed	Fast Read Dual Output Setting
		Bit[4:0] = 01000 8 Dummy Bits are needed	
8Dh	3Bh	Opcode for Single Input Dual Output Fast Read	
8Eh	80h	Bit[7:5] = 100 8 Mode Bits are needed	Fast Read Dual I/O Setting
		Bit[4:0] = 00000 No Dummy Bits are needed	
8Fh	BBh	Opcode for Dual Input Dual Output Fast Read	
90h	FEh	Bit[7:5]= 111 Reserved	Fast Read in QPI mode
		Bit[4]=1 Supports Quad input opcode & address and quad output data Fast Read	
		Bit[3:1]=111 Reserved	
		Bit[0]=0 Not support Dual Input opcode & address	

		and dual output data Fast Read	
91h	FFh	Reserved	
92h	FFh	Reserved	
93h	FFh	Reserved	
94h	FFh	Reserved	Fast Read Dual I/O in QPI Setting
95h	FFh	Reserved	
96h	00h	Bit[7:5]=000 No Mode Bits are needed	
		Bit[4:0]=00000 No Dummy Bits are needed	
97h	FFh	Reserved. Opcode Not to be supported.	
98h	FFh	Reserved	Fast Read Quad I/O in QPI Setting
99h	FFh	Reserved	
9Ah	44h	Bit[7:5]=010 8 Mode Bits are needed	
		Bit[4:0]=00100 8 Dummy Bits are needed($\leq 80\text{Mhz}$)	
9Bh	EBh	Opcode for Quad Input Quad Output Fast Read in QPI mode	
9Ch	0Ch	Sector type 1 size= 4Kbytes	Erase for Sector Type 1/2
9Dh	20h	Opcode for Erase of Sector Type 1	
9Eh	0Fh	Sector type 2 size= 32Kbytes	
9Fh	52h	Opcode for Erase of Sector Type 2	
A0h	10h	Sector type 3 size= 64Kbytes	Erase for Sector Type 3/4
A1h	D8h	Opcode for Erase of Sector Type 3	
A2h	00h	Sector type 4 size not to exist	
A3h	FFh	Reserved. Opcode Not to be supported.	
...(1)	FFh	Reserved	
E8h-EFh	xxh	Reserved	
F0h-FFh	xxh	Reserved	

Notes:

1. Data stored in Byte Address 10h to 7Fh & A4 to 90h to FFh are reserved, the value is FFh.
2. 1 Dword = 4 Bytes.
3. PID(x) = Parameter Identification Table(x)

10.40 Enter Secured OTP (B1h)

The Enter Secured OTP instruction is for entering the additional 4K-bit secured OTP mode. The additional 4K-bit secured OTP is independent from main array, which may be used to store unique serial number for system identifier. After entering the Secured OTP mode, and then follow standard read or program, procedure to read out the data or update data. The Secured OTP data cannot be updated again once it is lock-down

Please note that Write Status Register-1, Write Status Register-2 and Write Security Register instructions are not acceptable during the access of secure OTP region. Once security OTP is lock down, only commands related with read are valid.

The Enter Secured OTP instruction sequence is shown in figure 40.

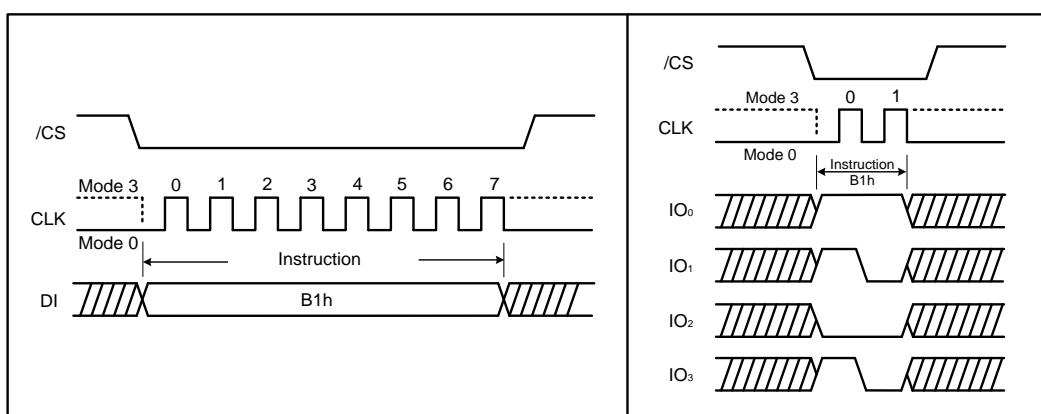


Figure 40. Enter Secured OTP instruction for SPI Mode (left) and QPI Mode (right)

10.41 Exit Secured OTP (C1h)

The Exit Secured OTP instruction is for exiting the additional 4K-bit secured OTP mode. (Please refer to figure 41).

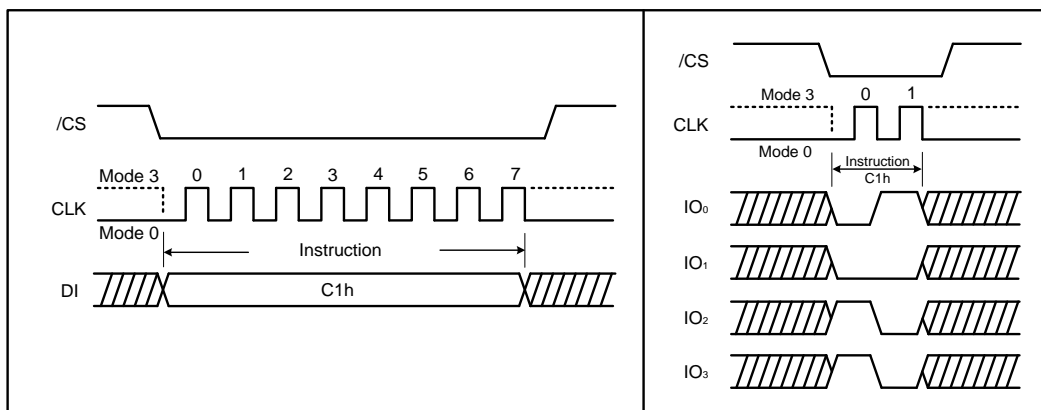


Figure 41. Exit Secured OTP instruction for SPI Mode (left) and QPI Mode (right)

10.42 Read Security Register (2Bh)

The Read Security Register can be read the value of Security Register bits at any time (even in program/erase/write status register-1 and write status register-2 condition) and continuously.

Secured OTP Indicator bit. The Secured OTP indicator bit shows the chip is locked by factory before ex-factory or not. When it is “0”, it indicates non-factory lock, “1” indicates factory-lock.

Lock-down Secured OTP (LDSO) bit. By writing Write Security Register instruction, the LDSO bit may be set to “1” for customer lock-down purpose. However, once the bit is set to “1” (Lock-down), the LDSO bit and the 4K-bit Secured OTP area cannot be updated any more. While it is in 4K-bit Secured OTP mode, array access is not allowed to write.

Security Register Definition

Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
x	x	x	x	x	x	LDSO (indicate if lock-down)	Secured OTP indicator bit
reserved	reserved	reserved	reserved	reserved	reserved	0 = not lock-down 1 =lock-down (cannot program/erase OTP)	0 = non factory lock 1 = factory lock
Volatile bit	Volatile bit	Volatile bit	Volatile bit	Volatile bit	Volatile bit	Non-Volatile bit	Non-Volatile bit

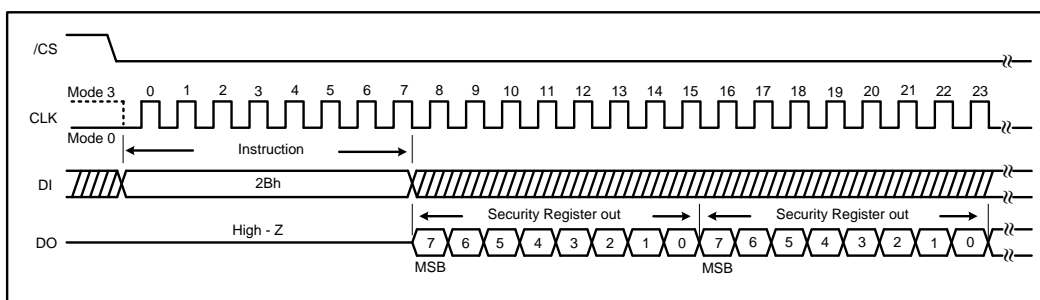


Figure 42a. Read Security Register instruction (SPI Mode)

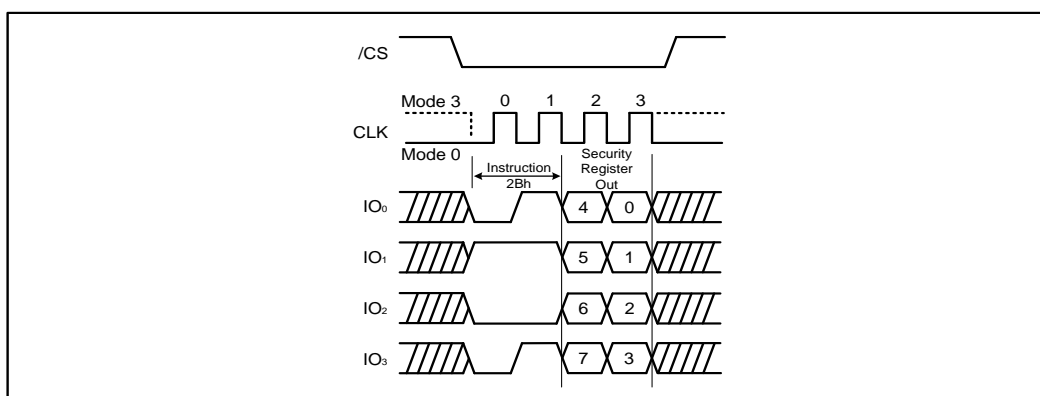


Figure 42b. Read Security Register instruction (QPI Mode)

10.43 Write Security Register (2Fh)

The Write Security Register instruction is for changing the values of Security Register bits. Unlike Write Status Register, the Write Enable instruction is not required before writing Write Security Register instruction. The Write Security Register instruction may change the value of bit1 (LDSO bit) for customer to lock-down the 4K-bit Secured OTP area. Once the LDSO bit is set to "1", the Secured OTP area cannot be updated any more.

The /CS must go high exactly at the boundary; otherwise, the instruction will be rejected and not executed.

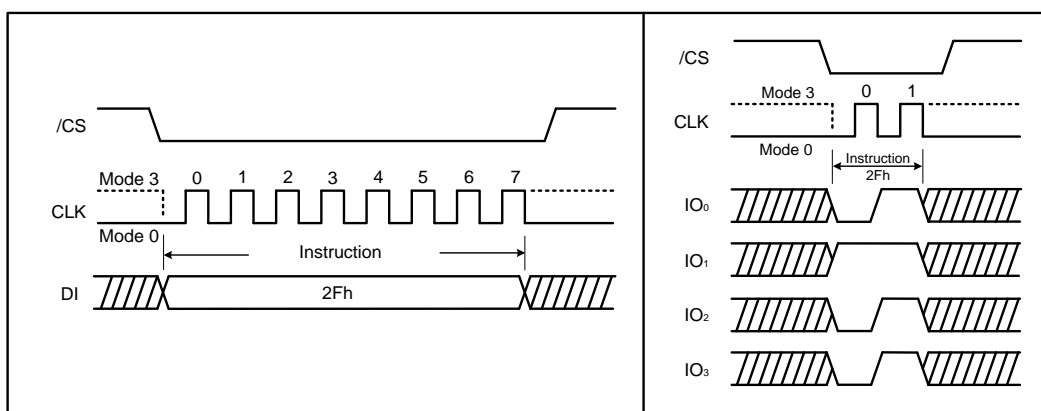


Figure 43. Write Security Register instruction for SPI Mode (left) and QPI Mode (right)

11. 4K-bit Secured OTP

It's for unique identifier to provide 4K-bit one-time-program area for setting device unique serial number which may be set by factory or system customer. Please refer to table of "4K-bit secured OTP definition".

- Security register bit 0 indicates whether the chip is locked by factory or not.
- To program the 4K-bit secured OTP by entering 4K-bit secured OTP mode (with ENSO command) and going through normal program procedure, and then exiting 4K-bit secured OTP mode by writing EXSO command
- Customer may lock-down bit1 as "1". Please refer to "table of security register definition" for security register bit definition and table of "4K-bit secured OTP definition" for address range definition.
- Note. Once lock-down whatever by factory or customer, it cannot be changed any more. While in 4K-bit secured OTP mode, array access is not allowed to write.

4K-bit secured OTP definition

Address range	Size	Standard Factory Lock	Customer Lock
000000 ~ 00000F	128-bit	ESN (Electrical Serial Number)	Determined by customer
000010 ~ 0001FF	3968-bit	N/A	

12. ELECTRICAL CHARACTERISTICS

12.1 Absolute Maximum Ratings ⁽¹⁾

PARAMETERS	SYMBOL	CONDITIONS	RANGE	UNIT
Supply Voltage	V _{CC}		-0.6 to V _{CC} +0.4	V
Voltage Applied to Any Pin	V _{IO}	Relative to Ground	-0.6 to V _{CC} +0.4	V
Transient Voltage on any Pin	V _{IOT}	<20nS Transient Relative to Ground	-1.0V to V _{CC} +1.0V	V
Storage Temperature	T _{STG}		-65 to +150	°C
Lead Temperature	T _{LEAD}		See Note ⁽²⁾	°C
Electrostatic Discharge Voltage	V _{ESD}	Human Body Model ⁽³⁾	-2000 to +2000	V

Notes:

1. This device has been designed and tested for the specified operation ranges. Proper operation outside of these levels is not guaranteed. Exposure to absolute maximum ratings may affect device reliability. Exposure beyond absolute maximum ratings may cause permanent damage.
2. Compliant with JEDEC Standard J-STD-20C for small body Sn-Pb or Pb-free (Green) assembly and the European directive on restrictions on hazardous substances (RoHS) 2002/95/EU.
3. JEDEC Std JESD22-A114A (C1=100pF, R1=1500 ohms, R2=500 ohms).

12.2 Operating Ranges

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNIT
Erase/Program Cycles	V _{CC}	FR = 133MHz (Single/Dual/Quad SPI) fR = 50MHz (Read Data 03h)	1.65	1.95	V
Ambient Operating Temperature	T _A	Industrial	-40	+85	°C

12.3 Endurance and Data Retention

PARAMETER	CONDITIONS	MIN	MAX	UNIT
Erase/Program Cycles	4KB sector, 32/64KB block or full chip.	100,000		Cycles
Data Retention	Full Temperature Range		20	years

12.4 Power-up Timing and Write Inhibit Threshold

PARAMETER	SYMBOL	SPEC		UNIT
		MIN	MAX	
VCC(min) to /CS Low	tVSL ⁽¹⁾	10		μs
Time Delay Before Write Instruction	tPUW ⁽¹⁾	1	10	ms
Write Inhibit Threshold Voltage	VWI ⁽¹⁾	1.0	1.4	V

Note:

1. These parameters are characterized only.

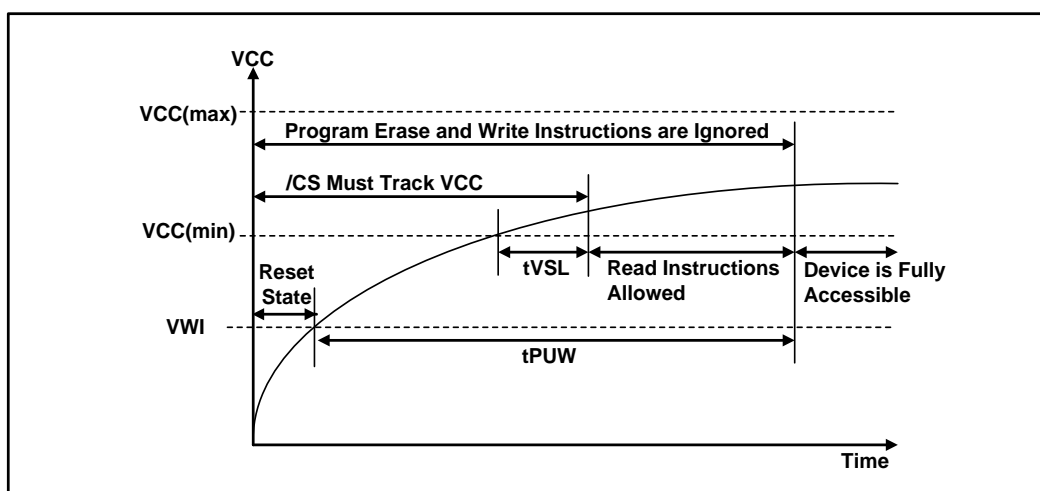


Figure 44. Power-up Timing and Voltage Levels

12.5 Program Acceleration via ACC Pin

The program acceleration function requires applying V_{HH} to the ACC input, and then waiting a period of t_{WC}. Minimum t_{VHH} (rise & fall times) is required for ACC to change to V_{HH} from V_{IL} or V_{IH}. Removing V_{HH} from the ACC pin returns the device to normal operation after a period of t_{WC}.

Only Read Status Register and Page Program operation are allowed when ACC is at (V_{HH}).

The start address must be entered by the multiples of 4-byte (for example xxxxx0, xxxxx4, xxxxx8, xxxxxC). Also the data must be entered with a minimum of 4-byte and multiples of 4-byte unit when Program Acceleration via ACC Pin.

PARAMETER	SYMBOL	SPEC		UNIT
		MIN	MAX	
/WP pin High Voltage	V _{HH} ⁽¹⁾	8.5	9.5	V
/WP pin Voltage rise and fall time	t _{VHH} ⁽¹⁾	2.2		μs
/WP at V _{HH} and V _{IL} or V _{IH} to first instruction	t _{WC} ⁽¹⁾	5		μs

Note:

- These parameters are characterized only.

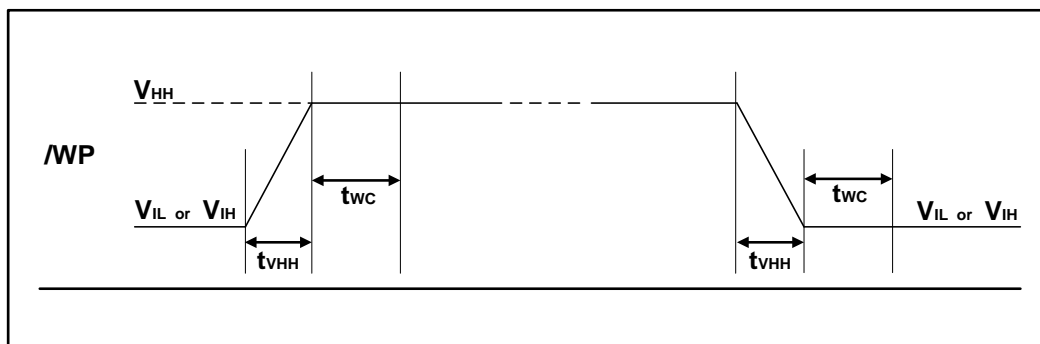


Figure 45. ACC Program acceleration Timing and Voltage Levels

12.6 DC Electrical Characteristics

PARAMETER	SYMBOL	CONDITION	SPEC			UNIT
			MIN	TYP	MAX	
Input Capacitance	CIN ⁽¹⁾	VIN=0V ⁽²⁾			6	pF
Output Capacitance	COUT ⁽¹⁾	VOUT=0V ⁽²⁾			8	pF
Input Leakage	ILI				±2	μA
I/O Leakage	ILO				±2	μA
Standby Current	ICC1	/CS=VCC VIN=GND or VCC		10	70	μA
Power-down Current	ICC2	/CS=VCC VIN=GND or VCC		2	20	μA
Current Read Data/ Dual/Quad 1MHz ⁽²⁾	ICC3	C=0.1 VCC / 0.9VCC IO=Open			7	mA
Current Read Data/ Dual/Quad 50MHz ⁽²⁾	ICC3	C=0.1 VCC / 0.9VCC IO=Open			15	mA
Current Read Data/ Dual/Quad 80MHz ⁽²⁾	ICC3	C=0.1 VCC / 0.9VCC IO=Open			18	mA
Current Read Data/ Dual/Quad 104MHz ⁽²⁾	ICC3	C=0.1 VCC / 0.9VCC IO=Open			20	mA
Current Read Data/ Dual/Quad 133MHz ⁽²⁾	ICC3	C=0.1 VCC / 0.9VCC IO=Open			27	mA
Current Write Status Register	ICC4	/CS=VCC		10	20	mA
Current page Program	ICC5	/CS=VCC		15	25	mA
Current Sector/Block Erase	ICC6	/CS=VCC		15	25	mA
Current Chip Erase	ICC7	/CS=VCC		15	25	mA
Input Low Voltages	VIL		-0.5		VCC x0.2	V
Input High Voltages	VIH		VCC x0.8		VCC +0.4	V
Output Low Voltages	VOL	IOL= 100μA			0.2	V
Output High Voltages	VOH	IOH=-100μA	VCC -0.2			V

1. Tested on sample basis and specified through design and characterization data, TA = 25°C, VCC = 1.8V.

2. Checked Board Pattern.

12.7 AC Measurement Conditions

PARAMETER	SYMBOL	SPEC		UNIT
		MIN	MAX	
Load Capacitance	C_L		30	pF
Input Rise and Fall Times	T_R, T_F		5	ns
Input Pulse Voltages	V_{IN}	0.2 V_{CC} to 0.8 V_{CC}		V
Input Timing Reference Voltages	IN	0.3 V_{CC} to 0.7 V_{CC}		V
Output Timing Reference Voltages	OUT	0.5 V_{CC} to 0.5 V_{CC}		V

Note:

1. Output Hi-Z is defined as the point where data out is no longer driven.

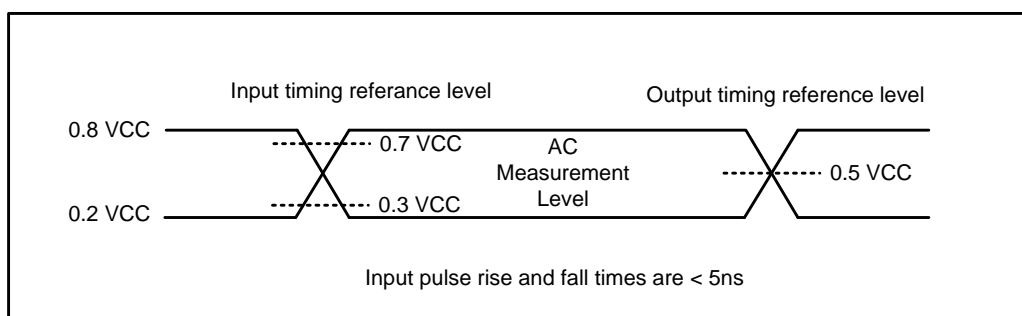


Figure 46. AC Measurement I/O Waveform

12.8 AC Electrical Characteristics

DESCRIPTION	SYMBOL	ALT	SPEC			UNIT
			MIN	TYP	MAX	
Clock frequency For all instructions, except Read Data (03h) 1.65V-1.95V VCC & Industrial Temperature	F _R	f _c	D.C.		133	MHz
Clock freq. Read Data instruction (03h)	f _R		D.C.		50	MHz
Clock High, Low Time except Read Data (03h)	t _{CLH} , t _{CLL} ⁽¹⁾		3.5			ns
Clock High, Low Time for Read Data (03h) instructions	t _{CRLH} , t _{CRLL} ⁽¹⁾		8			ns
Clock Rise Time peak to peak	t _{CLCH} ⁽²⁾		0.1			V/ns
Clock Fall Time peak to peak	t _{CHCL} ⁽²⁾		0.1			V/ns
/CS Active Setup Time relative to CLK	t _{SLCH}	t _{CSS}	5			ns
/CS Not Active Hold Time relative to CLK	t _{CHSL}		5			ns
Data In Setup Time	t _{DVCH}	t _{DSU}	2			ns
Data In Hold Time	t _{CHDX}	t _{DH}	3			ns
/CS Active Hold Time relative to CLK	t _{CHSH}		5			ns
/CS Not Active Setup Time relative to CLK	t _{SHCH}		5			ns
/CS Deselect Time (for Read instructions/ Write, Erase and Program instructions)	t _{SHSL}	t _{CSH}	30			ns
Output Disable Time	t _{SHQZ} ⁽²⁾	t _{DIS}			7	ns
Clock Low to Output Valid	t _{CLQV}	t _{V1}			6	ns
Clock Low to Output Valid (Except Main Read) ⁽³⁾	t _{CLQV}	t _{V2}			7	ns
Output Hold Time	t _{CLQX}	t _{HO}	1.5			ns
/Hold Active Setup Time relative to CLK	t _{HLCH}		5			ns

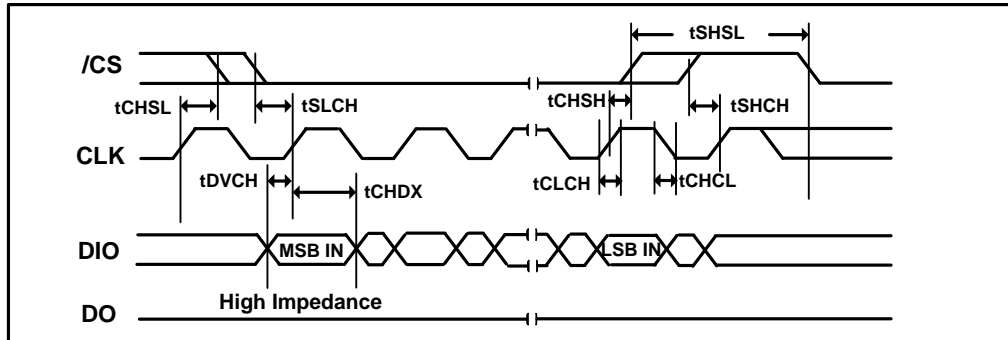
12.9 AC Electrical Characteristics (cont'd)

DESCRIPTION	SYMBOL	ALT	SPEC			UNIT
			MIN	TYP	MAX	
/HOLD Active Hold Time relative to CLK	tCHHH		5			ns
/HOLD Not Active Setup Time relative to CLK	tHHCH		5			ns
/HOLD Not Active Hold Time relative to CLK	tCHHL		5			ns
/HOLD to Output Low-Z	tHHQX ⁽²⁾	tLZ			7	ns
/HOLD to Output High-Z	tHLQZ ⁽²⁾	tHZ			12	ns
Write Protect Setup Time Before /CS Low	tWHS ⁽⁴⁾		20			ns
Write Protect Setup Time After /CS High	tSHWL ⁽⁴⁾		100			ns
/CS High to Power-down Mode	tDP ⁽²⁾				3	μs
/CS High to Standby Mode without Electronic Signature Read	tRES1 ⁽²⁾				30	μs
/CS High to Standby Mode with Electronic Signature Read	tRES2 ⁽²⁾				30	μs
/CS High to next Instruction after Suspend	tSUS ⁽²⁾				30	μs
CS High to next Instruction after Reset	tRST ⁽²⁾				30	μs
Write Status Register Time	tw			5	15	ms
Byte Program Time	tBP			5	150	μs
Page Program Time	tPP			0.6	5	ms
Page Program Time (ACC = 9V)	tEP			0.3	3	ms
Sector Erase Time(4KB)	tSE			0.06	0.4	s
Block Erase Time(32KB)	tBE1			0.2	1.5	s
Block Erase Time(64KB)	tBE2			0.35	2	s
Chip Erase Time	tCE			60	300	s

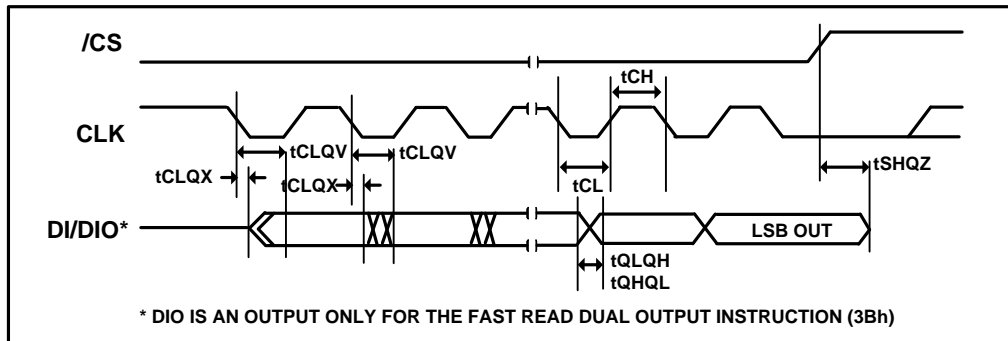
Notes:

1. Clock high + Clock low must be less than or equal to 1/fc.
2. Value guaranteed by design and/or characterization, not 100% tested in production.
3. Contains: Read Status Register-1,2/ Read Manufacturer/Device ID, Dual, Quad/ Read JEDEC ID/ Read Security Register/ Read Serial Flash Discovery Parameter.
4. Only applicable as a constraint for a Write Status Register instruction when Sector Protect Bit is set to 1.
5. Commercial temperature only applies to Fast Read (FR). Industrial temperature applies to all other parameters.

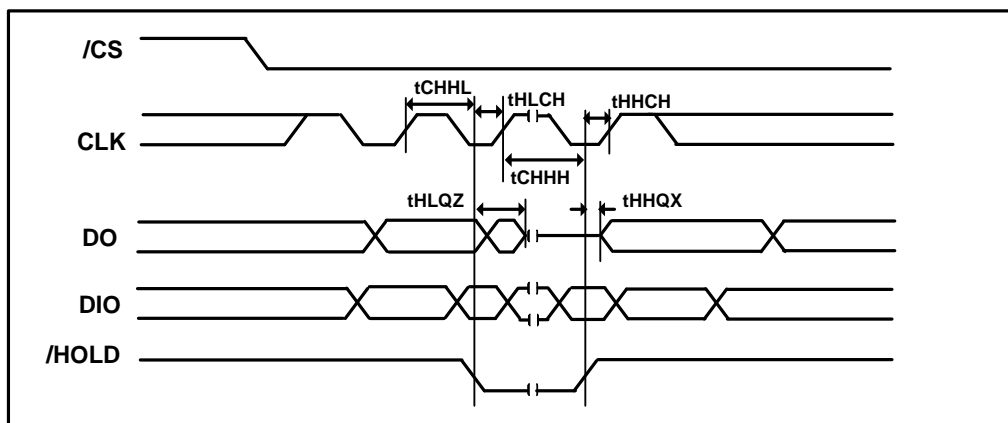
12.10 Input Timing



12.11 Output Timing

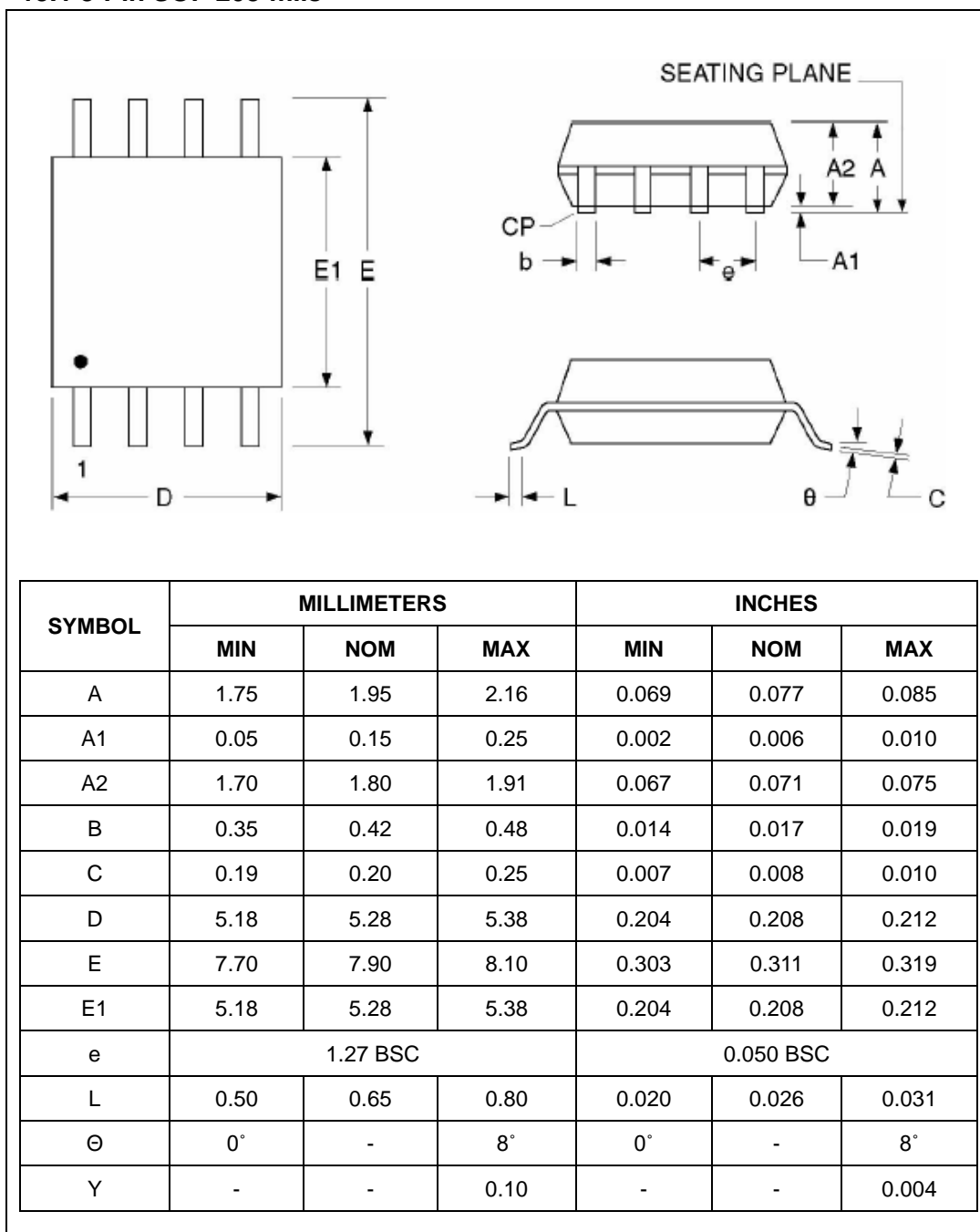


12.12 Hold Timing



13. PACKAGE SPECIFICATION

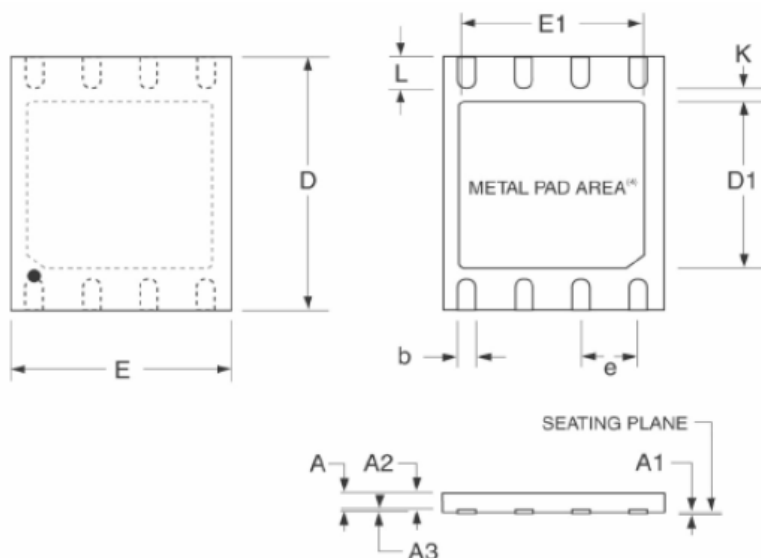
13.1 8-Pin SOP 208-mils



Notes:

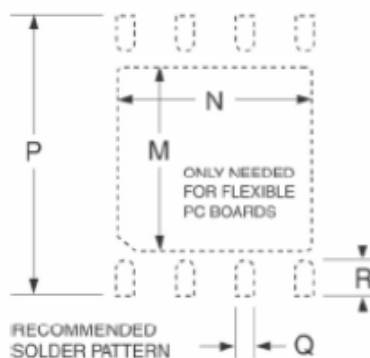
1. Controlling dimensions: inches, unless otherwise specified.
2. BSC = Basic lead spacing between centers.
3. Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
4. Formed leads shall be planar with respect to one another within. 0004 inches at the seating plane.

13.2 8-contact 6x5 WSON



SYMBOL	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.70	0.75	0.80	0.0276	0.0295	0.0315
A1	0.00	0.02	0.05	0.0000	0.0008	0.0019
A2		0.55			0.0126	
A3	0.19	0.20	0.25	0.0075	0.0080	0.0098
b	0.36	0.40	0.48	0.0138	0.0157	0.0190
D ⁽³⁾	5.90	6.00	6.10	0.2320	0.2360	0.2400
D1	3.30	3.40	3.50	0.1299	0.1338	0.1377
E	4.90	5.00	5.10	0.1930	0.1970	0.2010
E1 ⁽³⁾	4.25	4.30	4.35	0.1673	0.1692	0.1712
e ⁽²⁾	1.27 BSC			0.0500 BSC		
K	0.20			0.0080		
L	0.50	0.60	0.75	0.0197	0.0236	0.0295

13.4 8-contact 6x5 WSON (cont'd)



SYMBOL	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
SOLDER PATTERN						
M		3.40			0.1338	
N		4.30			0.1692	
P		6.00			0.2360	
Q		0.50			0.0196	
R		0.65			0.0255	

Notes:

1. Advanced Packaging Information; please contact Alliance Memory, Inc. for the latest minimum and maximum specifications.
2. BSC = Basic lead spacing between centers.
3. Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
4. The metal pad area on the bottom center of the package is connected to the device ground (GND pin). Avoid placement of exposed PCB bias under the pad.

PART NUMBERING SYSTEM

AS25F	1	128M	Q	-7	0	S / W	I	N
Alliance Memory Serial NOR Flash Series	Voltage 1 = 1.8V	Density 128Mb	Q = Multi IO (x1/x2/x4)	Speed 7 = 133MHz	Feature 0 = /WP Enabled, /HOLD Disabled 1 = /W disabled, /HOLD Enabled 2 = /W & /HOLD enabled 3 = /W & /HOLD disabled	Packing Type S = SOIC W = WSON	I = Industrial	Lead Free RoHS Compliant



Alliance Memory, Inc.
 12815 NE 124th Street Suite D
 Kirkland, WA 98034
 Tel: 425-898-4456
 Fax: 425-896-8628
www.alliancememory.com

Copyright © Alliance Memory
 All Rights Reserved

© Copyright 2007 Alliance Memory, Inc. All rights reserved. Our three-point logo, our name and Intelliwatt are trademarks or registered trademarks of Alliance. All other brand and product names may be the trademarks of their respective companies. Alliance reserves the right to make changes to this document and its products at any time without notice. Alliance assumes no responsibility for any errors that may appear in this document. The data contained herein represents Alliance's best data and/or estimates at the time of issuance. Alliance reserves the right to change or correct this data at any time, without notice. If the product described herein is under development, significant changes to these specifications are possible. The information in this product data sheet is intended to be general descriptive information for potential customers and users, and is not intended to operate as, or provide, any guarantee or warranty to any user or customer. Alliance does not assume any responsibility or liability arising out of the application or use of any product described herein, and disclaims any express or implied warranties related to the sale and/or use of Alliance products including liability or warranties related to fitness for a particular purpose, merchantability, or infringement of any intellectual property rights, except as express agreed to in Alliance's Terms and Conditions of Sale (which are available from Alliance). All sales of Alliance products are made exclusively according to Alliance's Terms and Conditions of Sale. The purchase of products from Alliance does not convey a license under any patent rights, copyrights; mask works rights, trademarks, or any other intellectual property rights of Alliance or third parties. Alliance does not authorize its products for use as critical components in life-supporting systems where a malfunction or failure may reasonably be expected to result in significant injury to the user, and the inclusion of Alliance products in such life-supporting systems implies that the manufacturer assumes all risk of such use and agrees to indemnify Alliance against all claims arising from such use.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Alliance Memory:

[AS25F1128MQ-70WINTR](#) [AS25F1128MQ-70SINTR](#) [AS25F1128MQ-70SIN](#) [AS25F1128MQ-70WIN](#)